

- Output Swing Includes Both Supply Rails
- Low Noise . . . 12 nV/√Hz Typ at f = 1 kHz
- Low Input Bias Current . . . 1 pA Typ
- Fully Specified for Both Single-Supply and Split-Supply Operation
- Low Power . . . 500 μA Max
- Common-Mode Input Voltage Range Includes Negative Rail
- Low Input Offset Voltage  
950 μV Max at T<sub>A</sub> = 25°C (TLV226xA)
- Wide Supply Voltage Range  
2.7 V to 8 V
- Macromodel Included
- Available in Q-Temp Automotive  
HighRel Automotive Applications  
Configuration Control / Print Support  
Qualification to Automotive Standards

## description

The TLV2262 and TLV2264 are dual and quad low voltage operational amplifiers from Texas Instruments. Both devices exhibit rail-to-rail output performance for increased dynamic range in single or split supply applications. The TLV226x family offers a compromise between the micro-power TLV225x and the ac performance of the TLC227x. It has low supply current for battery-powered applications, while still having adequate ac performance for applications that demand it. This family is fully characterized at 3 V and 5 V and is optimized for low-voltage applications. The noise performance has been dramatically improved over previous generations of CMOS amplifiers. Figure 1 depicts the low level of noise voltage for this CMOS amplifier, which has only 200 μA (typ) of supply current per amplifier.

The TLV226x, exhibiting high input impedance and low noise, are excellent for small-signal conditioning for high-impedance sources, such as piezoelectric transducers. Because of the micro-power dissipation levels combined with 3-V operation, these devices work well in hand-held monitoring and remote-sensing applications. In addition, the rail-to-rail output feature with single or split supplies makes this family a great choice when interfacing with analog-to-digital converters (ADCs). For precision applications, the TLV226xA family is available and has a maximum input offset voltage of 950 μV.

The TLV2262/4 also makes great upgrades to the TLV2332/4 in standard designs. They offer increased output dynamic range, lower noise voltage and lower input offset voltage. This enhanced feature set allows them to be used in a wider range of applications. For applications that require higher output drive and wider input voltage range, see the TLV2432 and TLV2442 devices. If your design requires single amplifiers, please see the TLV2211/21/31 family. These devices are single rail-to-rail operational amplifiers in the SOT-23 package. Their small size and low power consumption make them ideal for high density, battery-powered equipment.

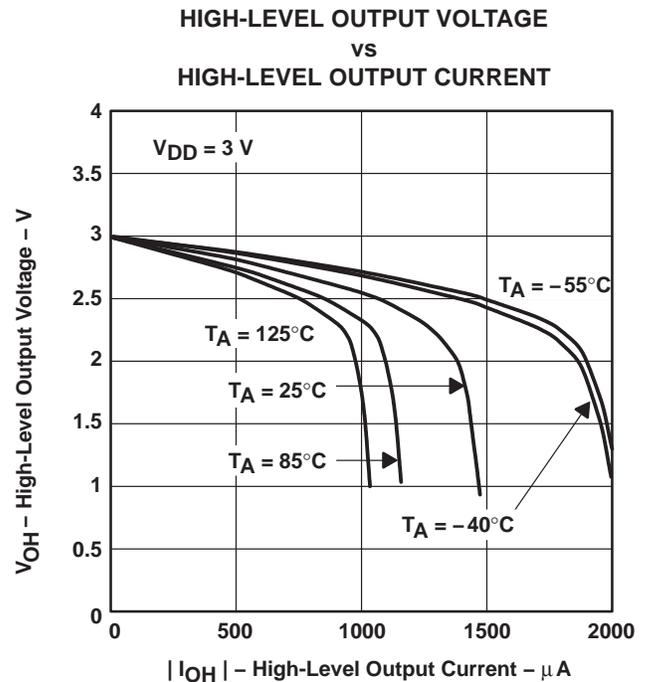


Figure 1



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Advanced LinCMOS is a trademark of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS  
INSTRUMENTS**

POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

Copyright © 1997–2006, Texas Instruments Incorporated  
On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

# TLV226x, TLV226xA Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

## TLV2262 AVAILABLE OPTIONS

T <sub>A</sub>	V <sub>IO</sub> max AT 25°C	PACKAGED DEVICES					
		SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	TSSOP (PW)	CERAMIC FLATPACK (U)
0°C to 70°C	2.5 mV	TLV2262CD	—	—	TLV2262CP	TLV2262CPWLE	—
–40°C to 125°C	950 μV 2.5 mV	TLV2262AID TLV2262ID	— —	— —	TLV2262AIP TLV2262IP	TLV2262AIPWLE —	— —
–40°C to 125°C	950 μV 2.5 mV	TLV2262AQD TLV2262QD	— —	— —	— —	— —	— —
–55°C to 125°C	950 μV 2.5 mV	— —	TLV2262AMFK TLV2262MFK	TLV2262AMJG TLV2262MJG	— —	— —	TLV2262AMU TLV2262MU

† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLV2262CDR).

‡ The PW package is available only left-end taped and reeled.

§ Chips are tested at 25°C.

¶ For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at [www.ti.com](http://www.ti.com).

## TLV2264 AVAILABLE OPTIONS

T <sub>A</sub>	V <sub>IO</sub> max AT 25°C	PACKAGED DEVICES					
		SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)	TSSOP (PW)	CERAMIC FLATPACK (W)
–40°C to 125°C	950 μV 2.5 mV	TLV2264AID TLV2264ID	— —	— —	TLV2264AIN TLV2264IN	TLV2264AIPWLE —	— —
–40°C to 125°C	950 μV 2.5 mV	TLV2264AQD TLV2264QD	— —	— —	— —	— —	— —
–55°C to 125°C	950 μV 2.5 mV	— —	TLV2264AMFK TLV2264MFK	TLV2264AMJ TLV2264MJ	— —	— —	TLV2264AMW TLV2264MW

† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLV2262IDR).

‡ The PW package is available only left-end taped and reeled.

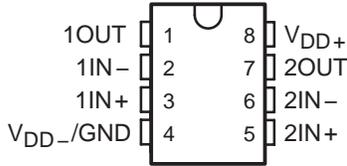
§ Chips are tested at 25°C.

¶ For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at [www.ti.com](http://www.ti.com).

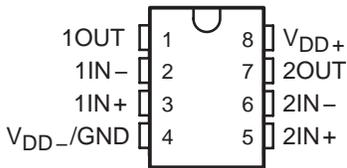
# TLV226x, TLV226xA Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

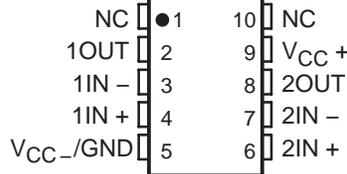
**TLV2262C, TLV2262AC  
TLV2262I, TLV2262AI  
TLV2262Q, TLV2262AQ  
D, P, OR PW PACKAGE  
(TOP VIEW)**



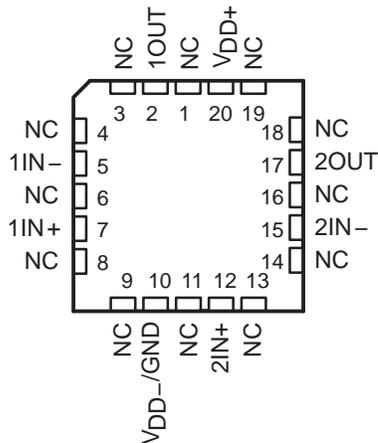
**TLV2262M, TLV2262AM  
JG PACKAGE  
(TOP VIEW)**



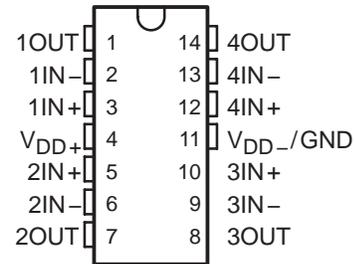
**TLV2662M, TLV2262AM  
U PACKAGE  
(TOP VIEW)**



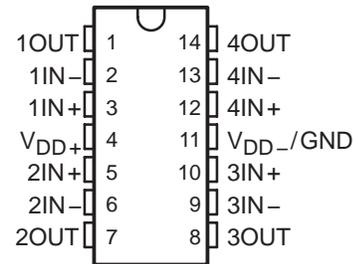
**TLV2262M, TLV2262AM  
FK PACKAGE  
(TOP VIEW)**



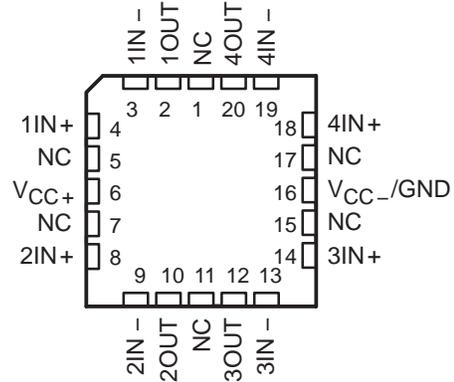
**TLV2264I, TLV2264AI  
TLV2264Q, TLV2264AQ  
D, N, OR PW PACKAGE  
(TOP VIEW)**



**TLV2264M, TLV2264AM  
J OR W PACKAGE  
(TOP VIEW)**



**TLV2264M, TLV2264AM  
FK PACKAGE  
(TOP VIEW)**

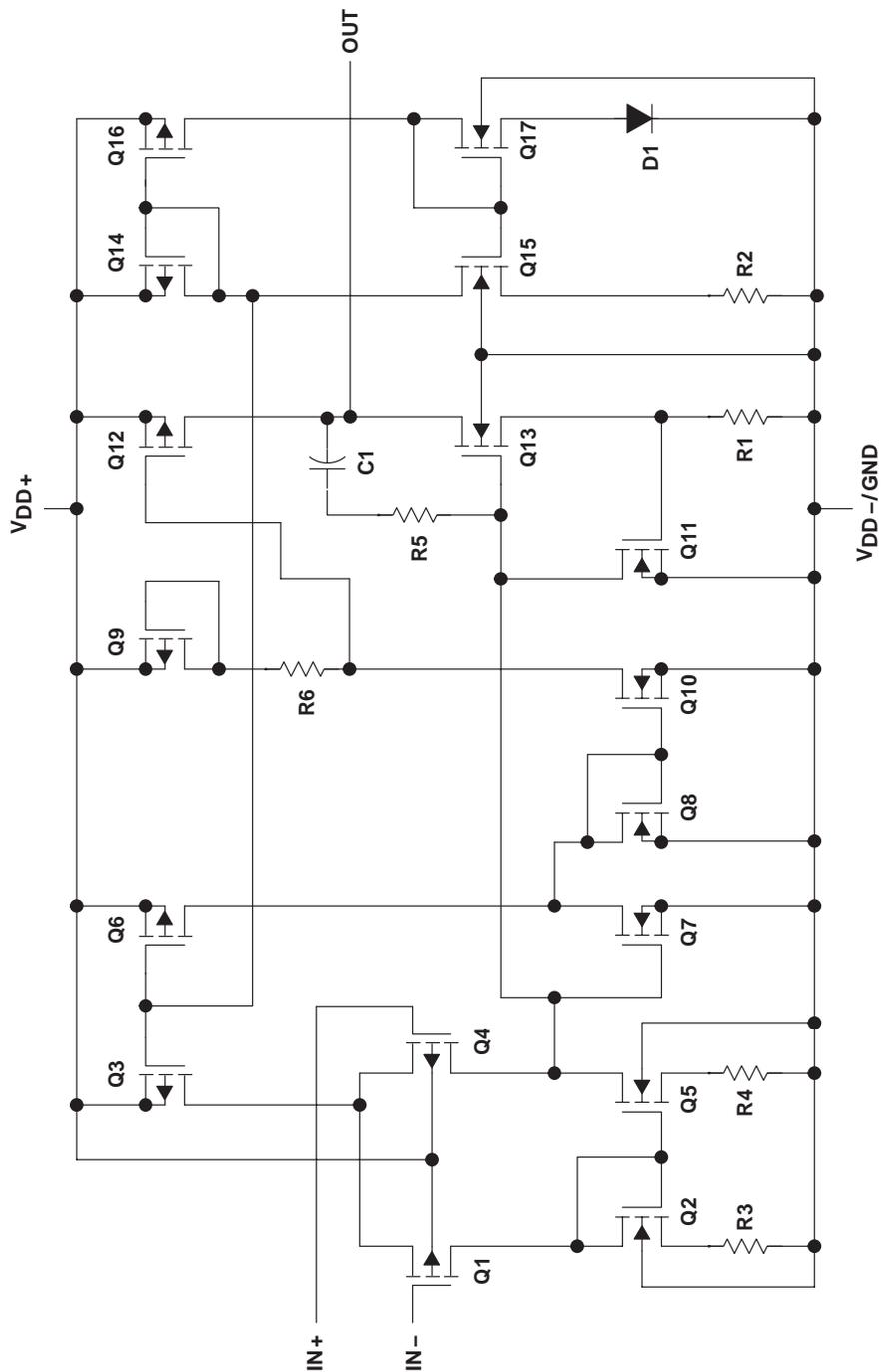


# TLV226x, TLV226xA

## Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

equivalent schematic (each amplifier)



ACTUAL DEVICE COMPONENT COUNT†	
COMPONENT	TLV2252
Transistors	38
Resistors	28
Diodes	9
Capacitors	3

ACTUAL DEVICE COMPONENT COUNT†	
COMPONENT	TLV2254
Transistors	76
Resistors	54
Diodes	18
Capacitors	6

† Includes both amplifiers and all ESD, bias, and trim circuitry

**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†**

Supply voltage, $V_{DD}$ (see Note 1)	16 V
Differential input voltage, $V_{ID}$ (see Note 2)	$\pm V_{DD}$
Input voltage range, $V_I$ (any input, see Note 1)	$V_{DD-} - 0.3 \text{ V}$ to $V_{DD+}$
Input current, $I_I$ (each input)	$\pm 5 \text{ mA}$
Output current, $I_O$	$\pm 50 \text{ mA}$
Total current into $V_{DD+}$	$\pm 50 \text{ mA}$
Total current out of $V_{DD-}$	$\pm 50 \text{ mA}$
Duration of short-circuit current (at or below) 25°C (see Note 3)	unlimited
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, $T_A$ : I suffix	-40°C to 125°C
Q suffix	-40°C to 125°C
M suffix	-55°C to 125°C
Storage temperature range, $T_{stg}$	-65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to  $V_{DD-}$ .
2. Differential voltages are at the noninverting input with respect to the inverting input. Excessive current flows when input is brought below  $V_{DD-} - 0.3 \text{ V}$ .
3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

**DISSIPATION RATING TABLE**

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D-8	725 mW	5.8 mW/°C	377 mW	145 mW
D-14	950 mW	7.6 mW/°C	494 mW	190 mW
FK	1375 mW	11.0 mW/°C	715 mW	275 mW
J	1375 mW	11.0 mW/°C	715 mW	275 mW
JG	1050 mW	8.4 mW/°C	—	210 mW
N	1150 mW	9.2 mW/°C	598 mW	—
P	1000 mW	8.0 mW/°C	520 mW	200 mW
PW-8	525 mW	4.2 mW/°C	273 mW	105 mW
PW-14	700 mW	5.6 mW/°C	364 mW	—
U	700 mW	5.5 mW/°C	—	150 mW
W	700 mW	5.5 mW/°C	370 mW	150 mW

**recommended operating conditions**

	I SUFFIX		Q SUFFIX		M SUFFIX		UNIT
	MIN	MAX	MIN	MAX	MIN	MAX	
Supply voltage, $V_{DD\pm}$ (see Note 1)	2.7	8	2.7	8	2.7	8	V
Input voltage range, $V_I$	$V_{DD-}$	$V_{DD+} - 1.3$	$V_{DD-}$	$V_{DD+} - 1.3$	$V_{DD-}$	$V_{DD+} - 1.3$	V
Common-mode input voltage, $V_{IC}$	$V_{DD-}$	$V_{DD+} - 1.3$	$V_{DD-}$	$V_{DD+} - 1.3$	$V_{DD-}$	$V_{DD+} - 1.3$	V
Operating free-air temperature, $T_A$	-40	125	-40	125	-55	125	°C

NOTE 1: All voltage values, except differential voltages, are with respect to  $V_{DD-}$ .

# TLV226x, TLV226xA

## Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

TLV2262I electrical characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2262I			TLV2262AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{DD\pm} = \pm 1.5\text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50\ \Omega$	25°C	300	2500		300	950	$\mu\text{V}$	
		Full range			3000		1500		
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 85°C	2			2			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C	0.003			0.003			$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	pA	
		85°C		150		150			
		Full range		800		800			
$I_{IB}$ Input bias current		25°C	1	60		1	60	pA	
	85°C		150		150				
	Full range		800		800				
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$ , $ V_{IO}  \leq 5\text{ mV}$	25°C	0 to 2	-0.3 to 2.2		0 to 2	-0.3 to 2.2	V	
		Full range	0 to 1.7		0 to 1.7				
$V_{OH}$ High-level output voltage	$I_{OH} = -20\ \mu\text{A}$	25°C	2.99			2.99			V
	$I_{OH} = -100\ \mu\text{A}$	25°C	2.85			2.85			
	$I_{OH} = -400\ \mu\text{A}$	Full range	2.825			2.825			
		25°C	2.7			2.7			
$V_{OL}$ Low-level output voltage	$V_{IC} = 1.5\text{ V}$ , $I_{OL} = 50\ \mu\text{A}$	25°C	10			10			mV
		25°C	100			100			
	$V_{IC} = 1.5\text{ V}$ , $I_{OL} = 500\ \mu\text{A}$	Full range	150			150			
		25°C	200			200			
$AVD$ Large-signal differential voltage amplification	$V_{IC} = 1.5\text{ V}$ , $V_O = 1\text{ V to } 2\text{ V}$	$R_L = 50\ \text{k}\Omega$ ‡	25°C	60	100		60	100	V/mV
			Full range	30			30		
		$R_L = 1\ \text{M}\Omega$ ‡	25°C	100			100		
$r_{i(d)}$ Differential input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$
$r_{i(c)}$ Common-mode input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$
$c_{i(c)}$ Common-mode input capacitance	$f = 10\ \text{kHz}$ , P package	25°C	8			8			pF
$z_o$ Closed-loop output impedance	$f = 100\ \text{kHz}$ , $A_V = 10$	25°C	270			270			$\Omega$
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to } 1.7\text{ V}$ , $V_O = 1.5\text{ V}$ , $R_S = 50\ \Omega$	25°C	65	75		65	77	dB	
		Full range	60			60			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 2.7\text{ V to } 8\text{ V}$ , $V_{IC} = V_{DD}/2$ , No load	25°C	80	95		80	100	dB	
		Full range	80			80			

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$ .

‡ Referenced to 1.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLV2262I electrical characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$  (unless otherwise noted) (continued)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2262I			TLV2262AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$I_{DD}$ Supply current	$V_O = 1.5\text{ V}$ , No load	25°C	400	500		400	500	$\mu\text{A}$	
		Full range		500			500		

† Full range is – 40°C to 125°C.

**TLV2262I operating characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2262I			TLV2262AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 1.1\text{ V to }1.9\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C	0.35	0.55		0.35	0.55	$\text{V}/\mu\text{s}$	
		Full range	0.3			0.3			
$V_n$ Equivalent input noise voltage	$f = 10\text{ Hz}$	25°C		43			43	$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\text{ kHz}$	25°C		12			12		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$	25°C		0.6			0.6	$\mu\text{V}$	
	$f = 0.1\text{ Hz to }10\text{ Hz}$	25°C		1			1		
$I_n$ Equivalent input noise current		25°C		0.6			0.6	$\text{fA}/\sqrt{\text{Hz}}$	
THD + N Total harmonic distortion plus noise	$V_O = 0.5\text{ V to }2.5\text{ V}$ , $f = 20\text{ kHz}$ , $R_L = 50\text{ k}\Omega$ ‡	$A_V = 1$		0.03%			0.03%		
		$A_V = 10$		0.05%			0.05%		
Gain-bandwidth product	$f = 1\text{ kHz}$ , $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C		0.67			0.67	MHz	
$B_{OM}$ Maximum output-swing bandwidth	$V_{O(PP)} = 1\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $A_V = 1$ , $C_L = 100\text{ pF}$ ‡	25°C		395			395	kHz	
$t_s$ Settling time	$A_V = -1$ , Step = 1 V to 2 V, $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	$T_o = 0.1\%$		5.6			5.6	$\mu\text{s}$	
		$T_o = 0.01\%$		12.5			12.5		
$\phi_m$ Phase margin at unity gain	$R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C		55°			55°		
		25°C		11			11		
Gain margin		25°C		11			11	dB	

† Full range is – 40°C to 125°C.

‡ Referenced to 1.5 V

# TLV226x, TLV226xA Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

TLV2262I electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2262I			TLV2262AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{DD} = \pm 2.5\text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50\ \Omega$	25°C	300	2500		300	950	$\mu\text{V}$	
		Full range			3000		1500		
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 85°C	2			2			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C	0.003			0.003			$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	pA	
		85°C		150		150			
	Full range		800		800				
$I_{IB}$ Input bias current	25°C	1	60		1	60	pA		
	85°C		150		150				
	Full range		800		800				
$V_{ICR}$ Common-mode input voltage range	$ V_{IO}  \leq 5\text{ mV}$ , $R_S = 50\ \Omega$	25°C	0 to 4	-0.3 to 4.2		0 to 4	-0.3 to 4.2	V	
		Full range	0 to 3.5		0 to 3.5				
$V_{OH}$ High-level output voltage	$I_{OH} = -20\ \mu\text{A}$ $I_{OH} = -100\ \mu\text{A}$ $I_{OH} = -400\ \mu\text{A}$	25°C	4.99		4.99		V		
		25°C	4.85	4.94	4.85	4.94			
		Full range	4.82		4.82				
		25°C	4.7	4.85	4.7	4.85			
$V_{OL}$ Low-level output voltage	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 50\ \mu\text{A}$ $V_{IC} = 2.5\text{ V}$ , $I_{OL} = 500\ \mu\text{A}$ $V_{IC} = 2.5\text{ V}$ , $I_{OL} = 1\text{ mA}$	25°C	0.01		0.01		V		
		25°C	0.09	0.15	0.09	0.15			
		Full range	0.15		0.15				
		25°C	0.2	0.3	0.2	0.3			
$A_{VD}$ Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}$ , $V_O = 1\text{ V to }4\text{ V}$	25°C	$R_L = 50\text{ k}\Omega$ ‡	80	170	80	170	V/mV	
			Full range	55		55			
		25°C	$R_L = 1\text{ M}\Omega$ ‡	550		550			
$r_{i(d)}$ Differential input resistance		25°C	10 <sup>12</sup>		10 <sup>12</sup>		$\Omega$		
$r_{i(c)}$ Common-mode input resistance		25°C	10 <sup>12</sup>		10 <sup>12</sup>		$\Omega$		
$c_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$ , P package	25°C	8		8		pF		
$z_o$ Closed-loop output impedance	$f = 100\text{ kHz}$ , $A_V = 10$	25°C	240		240		$\Omega$		
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }2.7\text{ V}$ , $V_O = 2.5\text{ V}$ , $R_S = 50\ \Omega$	25°C	70	83	70	83	dB		
		Full range	70		70				
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 4.4\text{ V to }8\text{ V}$ , $V_{IC} = V_{DD}/2$ , No load	25°C	80	95	80	95	dB		
		Full range	80		80				

† Full range is -40°C to 125°C.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLV2262I electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted) (continued)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2262I			TLV2262AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$I_{DD}$ Supply current	$V_O = 2.5\text{ V}$ , No load	25°C		400	500		400	500	$\mu\text{A}$
		Full range			500			500	

† Full range is – 40°C to 125°C.

**TLV2262I operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2262I			TLV2262AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 1.5\text{ V to }3.5\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C	0.35	0.55		0.35	0.55		$\text{V}/\mu\text{s}$
		Full range	0.3			0.3			
$V_n$ Equivalent input noise voltage	$f = 10\text{ Hz}$	25°C		40			40		$\text{nV}/\sqrt{\text{Hz}}$
	$f = 1\text{ kHz}$	25°C		12			12		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$	25°C		0.7			0.7		$\mu\text{V}$
	$f = 0.1\text{ Hz to }10\text{ Hz}$	25°C		1.3			1.3		
$I_n$ Equivalent input noise current		25°C		0.6			0.6	$\text{fA}/\sqrt{\text{Hz}}$	
THD + N Total harmonic distortion plus noise	$V_O = 0.5\text{ V to }2.5\text{ V}$ , $f = 20\text{ kHz}$ , $R_L = 50\text{ k}\Omega$ ‡	$A_V = 1$		0.017%			0.017%		
		$A_V = 10$		0.03%			0.03%		
Gain-bandwidth product	$f = 50\text{ kHz}$ , $C_L = 100\text{ pF}$ ‡, $R_L = 50\text{ k}\Omega$ ‡	25°C		0.71			0.71	MHz	
BOM Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $A_V = 1$ , $C_L = 100\text{ pF}$ ‡	25°C		185			185	kHz	
$t_s$ Settling time	$A_V = -1$ , Step = 0.5 V to 2.5 V, $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	To 0.1%		6.4			6.4	$\mu\text{s}$	
		To 0.01%		14.1			14.1		
$\phi_m$ Phase margin at unity gain	$R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C		56°			56°		
Gain margin		25°C		11			11	dB	

† Full range is – 40°C to 125°C.

‡ Referenced to 2.5 V

# TLV226x, TLV226xA Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

TLV2264I electrical characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2264I			TLV2264AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage		25°C	300	2500		300	950	$\mu\text{V}$	
		Full range			3000		1500		
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 85°C	2			2			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)	$V_{DD\pm} = \pm 1.5\text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50\ \Omega$	25°C	0.003			0.003			$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	pA	
		85°C		150		150			
		Full range		800		800			
$I_{IB}$ Input bias current		25°C	1	60		1	60	pA	
		85°C		150		150			
Full range		800		800					
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$ , $ V_{IO}  \leq 5\text{ mV}$	25°C	0 to 2	-0.3 to 2.2		0 to 2	-0.3 to 2.2	V	
		Full range	0 to 1.7		0 to 1.7				
$V_{OH}$ High-level output voltage	$I_{OH} = -20\ \mu\text{A}$	25°C	2.99			2.99			V
	$I_{OH} = -100\ \mu\text{A}$	25°C	2.85			2.85			
		Full range	2.825			2.825			
	$I_{OH} = -400\ \mu\text{A}$	25°C	2.7			2.7			
Full range		2.65			2.65				
$V_{OL}$ Low-level output voltage	$V_{IC} = 1.5\text{ V}$ , $I_{OL} = 50\ \mu\text{A}$	25°C	10			10			mV
		25°C	100			100			
	$V_{IC} = 1.5\text{ V}$ , $I_{OL} = 500\ \mu\text{A}$	Full range	150			150			
		$V_{IC} = 1.5\text{ V}$ , $I_{OL} = 1\text{ mA}$	25°C	200			200		
Full range	300			300					
$A_{VD}$ Large-signal differential voltage amplification	$V_{IC} = 1.5\text{ V}$ , $V_O = 1\text{ to }2\text{ V}$	$R_L = 50\ \text{k}\Omega$ ‡	25°C	60	100	60	100	V/mV	
			Full range	30			30		
		$R_L = 1\ \text{M}\Omega$ ‡	25°C	100			100		
$r_{i(d)}$ Differential input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$
$r_{i(c)}$ Common-mode input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$
$c_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$ , N package	25°C	8			8			pF
$z_o$ Closed-loop output impedance	$f = 100\text{ kHz}$ , $A_V = 10$	25°C	270			270			$\Omega$
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }1.7\text{ V}$ , $V_O = 1.5\text{ V}$ , $R_S = 50\ \Omega$	25°C	65	75		65	77	dB	
		Full range	60			60			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 2.7\text{ V to }8\text{ V}$ , $V_{IC} = V_{DD}/2$ , No load	25°C	80	95		80	100	dB	
		Full range	80			80			

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$ .

‡ Referenced to 1.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLV2264I electrical characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$  (unless otherwise noted) (continued)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2264I			TLV2264AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$I_{DD}$	Supply current (four amplifiers)	$V_O = 1.5\text{ V}$ , No load	25°C	0.8	1	0.8	1	mA	
			Full range		1		1		

† Full range is – 40°C to 125°C.

**TLV2264I operating characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2264I			TLV2264AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain $V_O = 0.7\text{ V}$ to $1.7\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C	0.35	0.55	0.35	0.55	$\text{V}/\mu\text{s}$		
		Full range	0.3		0.3				
$V_n$	Equivalent input noise voltage $f = 10\text{ Hz}$ $f = 1\text{ kHz}$	25°C		43		43	$\text{nV}/\sqrt{\text{Hz}}$		
		25°C		12		12			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage $f = 0.1\text{ Hz}$ to $1\text{ Hz}$ $f = 0.1\text{ Hz}$ to $10\text{ Hz}$	25°C		0.6		0.6	$\mu\text{V}$		
		25°C		1		1			
$I_n$	Equivalent input noise current	25°C		0.6		0.6	$\text{fA}/\sqrt{\text{Hz}}$		
THD + N	Total harmonic distortion plus noise $V_O = 0.5\text{ V}$ to $2.5\text{ V}$ , $f = 20\text{ kHz}$ , $R_L = 50\text{ k}\Omega$ ‡	$A_V = 1$	25°C			0.03%	0.03%		
		$A_V = 10$	25°C			0.05%	0.05%		
	Gain-bandwidth product $f = 1\text{ kHz}$ , $C_L = 100\text{ pF}$ ‡	$R_L = 50\text{ k}\Omega$ ‡	25°C	0.67			0.67	MHz	
$B_{OM}$	Maximum output-swing bandwidth $V_{O(PP)} = 1\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡	$A_V = 1$ , $C_L = 100\text{ pF}$ ‡	25°C	395			395	kHz	
$t_s$	Settling time $A_V = -1$ , Step = $1\text{ V}$ to $2\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	To 0.1%	25°C			5.6	5.6	$\mu\text{s}$	
		To 0.01%	25°C			12.5	12.5		
$\phi_m$	Phase margin at unity gain $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C	55°			55°			
		25°C	11			11		dB	

† Full range is – 40°C to 125°C.

‡ Referenced to 1.5 V

# TLV226x, TLV226xA Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

TLV2264I electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2264I			TLV2264AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
$V_{IO}$ Input offset voltage		25°C	300	2500		300	950	$\mu\text{V}$		
		Full range			3000		1500			
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 85°C	2			2			$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)	$V_{DD\pm} = \pm 2.5\text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50\ \Omega$	25°C	0.003			0.003			$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	pA		
		85°C				150				
		Full range				800				
$I_{IB}$ Input bias current		25°C	1	60		1	60	pA		
		85°C				150				
	Full range				800					
$V_{ICR}$ Common-mode input voltage range	$ V_{IO}  \leq 5\text{ mV}$ , $R_S = 50\ \Omega$	25°C	0 to 4	-0.3 to 4.2		0 to 4	-0.3 to 4.2	V		
		Full range	0 to 3.5			0 to 3.5				
$V_{OH}$ High-level output voltage	$I_{OH} = -20\ \mu\text{A}$	25°C	4.99			4.99			V	
		25°C	4.85	4.94		4.85	4.94			
		Full range	4.82			4.82				
		25°C	4.7	4.85		4.7	4.85			
$V_{OL}$ Low-level output voltage	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = -400\ \mu\text{A}$	25°C	0.01			0.01			V	
		25°C	0.09	0.15		0.09	0.15			
		Full range	0.15			0.15				
		25°C	0.2	0.3		0.2	0.3			
$A_{VD}$ Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}$ , $V_O = 1\text{ V to }4\text{ V}$	$R_L = 50\ \text{k}\Omega^\ddagger$	25°C	80	170		80	170	V/mV	
			Full range	55			55			
		$R_L = 1\ \text{M}\Omega^\ddagger$	25°C	550			550			
			Full range	0.3			0.3			
$r_{i(d)}$ Differential input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$	
$r_{i(c)}$ Common-mode input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$	
$C_{i(c)}$ Common-mode input capacitance	$f = 10\ \text{kHz}$ , N package	25°C	8			8			pF	
$z_o$ Closed-loop output impedance	$f = 100\ \text{kHz}$ , $A_V = 10$	25°C	240			240			$\Omega$	
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }2.7\text{ V}$ , $V_O = 2.5\text{ V}$ , $R_S = 50\ \Omega$	25°C	70	83		70	83	dB		
		Full range	70			70				
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 4.4\text{ V to }8\text{ V}$ , $V_{IC} = V_{DD}/2$ , No load	25°C	80	95		80	95	dB		
		Full range	80			80				

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$ .

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLV2264I electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted) (continued)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2264I			TLV2264AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$I_{DD}$	Supply current (four amplifiers)	$V_O = 2.5\text{ V}$ , No load	25°C	0.8	1	0.8	1	mA	
			Full range		1		1		

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$ .

**TLV2264I operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2264I			TLV2264AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR	Slew rate at unity gain $V_O = 1.4\text{ V}$ to $2.6\text{ V}$ , $C_L = 100\text{ pF}$ ‡	$R_L = 50\text{ k}\Omega$ ‡	25°C	0.35	0.55	0.35	0.55	$\text{V}/\mu\text{s}$		
			Full range	0.3		0.3				
$V_n$	Equivalent input noise voltage	$f = 10\text{ Hz}$	25°C	40			40			$\text{nV}/\sqrt{\text{Hz}}$
			$f = 1\text{ kHz}$	12			12			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz}$ to $1\text{ Hz}$	25°C	0.7			0.7			$\mu\text{V}$
		$f = 0.1\text{ Hz}$ to $10\text{ Hz}$	25°C	1.3			1.3			
$I_n$	Equivalent input noise current		25°C	0.6			0.6			$\text{fA}/\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise $V_O = 0.5\text{ V}$ to $2.5\text{ V}$ , $f = 20\text{ kHz}$ , $R_L = 50\text{ k}\Omega$ ‡	$A_V = 1$	25°C	0.017%			0.017%			
		$A_V = 10$		0.03%			0.03%			
	Gain-bandwidth product $f = 50\text{ kHz}$ , $C_L = 100\text{ pF}$ ‡	$R_L = 50\text{ k}\Omega$ ‡	25°C	0.71			0.71			MHz
BOM	Maximum output-swing bandwidth $V_{O(PP)} = 2\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡	$A_V = 1$ , $C_L = 100\text{ pF}$ ‡	25°C	185			185			kHz
$t_s$	Settling time $A_V = -1$ , Step = $0.5\text{ V}$ to $2.5\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	$T_o = 0.1\%$	25°C	6.4			6.4			$\mu\text{s}$
		$T_o = 0.01\%$		14.1			14.1			
$\phi_m$	Phase margin at unity gain $R_L = 50\text{ k}\Omega$ ‡	$C_L = 100\text{ pF}$ ‡	25°C	56°			56°			
	Gain margin		25°C	11			11			

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$ .

‡ Referenced to  $2.5\text{ V}$

# TLV226x, TLV226xA Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

TLV2262Q and TLV2262M electrical characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2262Q, TLV2262M			TLV2262AQ, TLV2262AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
$V_{IO}$ Input offset voltage		25°C	300	2500		300	950	$\mu\text{V}$		
		Full range		3000		1500				
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 125°C	2			2			$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)	$V_{DD\pm} = \pm 1.5\text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50\ \Omega$	25°C	0.003			0.003			$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	pA		
		125°C		800		800				
$I_{IB}$ Input bias current		25°C	1	60		1	60	pA		
		125°C		800		800				
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$ , $ V_{IO}  \leq 5\text{ mV}$	25°C	0 to 2	-0.3 to 2.2		0 to 2	-0.3 to 2.2	V		
		Full range	0 to 1.7			0 to 1.7				
$V_{OH}$ High-level output voltage	$I_{OH} = -20\ \mu\text{A}$	25°C	2.99			2.99			V	
	$I_{OH} = -100\ \mu\text{A}$	25°C	2.85			2.85				
	$I_{OH} = -400\ \mu\text{A}$	Full range	2.82			2.82				
		25°C	2.7			2.7				
$V_{OL}$ Low-level output voltage	$V_{IC} = 1.5\text{ V}$ , $I_{OL} = 50\ \mu\text{A}$	25°C	10			10			mV	
	$V_{IC} = 1.5\text{ V}$ , $I_{OL} = 500\ \mu\text{A}$	25°C	100	150		100	150			
		Full range	165			165				
	$V_{IC} = 1.5\text{ V}$ , $I_{OL} = 1\text{ mA}$	25°C	200	300		200	300			
$A_{VD}$ Large-signal differential voltage amplification	$V_{IC} = 1.5\text{ V}$ , $V_O = 1\text{ V to }2\text{ V}$	$R_L = 50\ \text{k}\Omega$ ‡	25°C	60	100		60	100	V/mV	
		$R_L = 1\ \text{M}\Omega$ ‡	Full range	25			25			
			25°C	100			100			
$r_{i(d)}$ Differential input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$	
$r_{i(c)}$ Common-mode input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$	
$C_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$ , P package	25°C	8			8			pF	
$z_o$ Closed-loop output impedance	$f = 100\text{ kHz}$ , $A_V = 10$	25°C	270			270			$\Omega$	
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }1.7\text{ V}$ , $V_O = 1.5\text{ V}$ , $R_S = 50\ \Omega$	25°C	65	75		65	77	dB		
		Full range	60			60				
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 2.7\text{ V to }8\text{ V}$ , $V_{IC} = V_{DD}/2$ , No load	25°C	80	95		80	100	dB		
		Full range	80			80				

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part,  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

‡ Referenced to 1.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLV2262Q and TLV2262M electrical characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$  (unless otherwise noted) (continued)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2262Q, TLV2262M			TLV2262AQ, TLV2262AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$I_{DD}$ Supply current	$V_O = 1.5\text{ V}$ , No load	25°C	400	500		400	500	$\mu\text{A}$	
		Full range		500		500			

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part,  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

**TLV2262Q and TLV2262M operating characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2262Q, TLV2262M			TLV2262AQ, TLV2262AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 0.5\text{ V}$ to $1.7\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C	0.35	0.55		0.35	0.55	$\text{V}/\mu\text{s}$	
		Full range	0.25			0.25			
$V_n$ Equivalent input noise voltage	$f = 10\text{ Hz}$	25°C		43			43	$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\text{ kHz}$	25°C		12			12		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz}$ to $1\text{ Hz}$	25°C		0.6			0.6	$\mu\text{V}$	
	$f = 0.1\text{ Hz}$ to $10\text{ Hz}$	25°C		1			1		
$I_n$ Equivalent input noise current		25°C		0.6			0.6	$\text{fA}/\sqrt{\text{Hz}}$	
THD + N Total harmonic distortion plus noise	$V_O = 0.5\text{ V}$ to $2.5\text{ V}$ , $f = 20\text{ kHz}$ , $R_L = 50\text{ k}\Omega$ ‡	$A_V = 1$		0.03%			0.03%		
		$A_V = 10$		0.05%			0.05%		
Gain-bandwidth product	$f = 1\text{ kHz}$ , $C_L = 100\text{ pF}$ ‡	$R_L = 50\text{ k}\Omega$ ‡,	25°C		0.67		0.67	MHz	
BOM Maximum output-swing bandwidth	$V_{O(PP)} = 1\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡,	$A_V = 1$ , $C_L = 100\text{ pF}$ ‡	25°C		395		395	kHz	
$t_s$ Settling time	$A_V = -1$ , Step = $1\text{ V}$ to $2\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	$T_o = 0.1\%$	25°C		5.6		5.6	$\mu\text{s}$	
		$T_o = 0.01\%$			12.5		12.5		
$\phi_m$ Phase margin at unity gain	$R_L = 50\text{ k}\Omega$ ‡,	$C_L = 100\text{ pF}$ ‡	25°C		55°		55°		
Gain margin			25°C		11		11		dB

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part,  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

‡ Referenced to  $1.5\text{ V}$

# TLV226x, TLV226xA Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

TLV2262Q and TLV2262M electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2262Q, TLV2262M			TLV2262AQ, TLV2262AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{DD} = \pm 2.5\text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50\ \Omega$	25°C	300	2500		300	950	$\mu\text{V}$	
		Full range		3000		1500			
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 125°C	2			2			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C	0.003			0.003			$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	pA	
		125°C	800			800			
$I_{IB}$ Input bias current		25°C	1	60		1	60	pA	
		125°C	800			800			
$V_{ICR}$ Common-mode input voltage range	$ V_{IO}  \leq 5\text{ mV}$ , $R_S = 50\ \Omega$	25°C	0 to 4	-0.3 to 4.2		0 to 4	-0.3 to 4.2	V	
		Full range	0 to 3.5		0 to 3.5				
$V_{OH}$ High-level output voltage	$I_{OH} = -20\ \mu\text{A}$	25°C	4.99			4.99			V
	$I_{OH} = -100\ \mu\text{A}$	25°C	4.85	4.94		4.85	4.94		
	$I_{OH} = -400\ \mu\text{A}$	Full range	4.82			4.82			
		25°C	4.7	4.85		4.7	4.85		
$V_{OL}$ Low-level output voltage	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 50\ \mu\text{A}$	25°C	0.01			0.01			V
		25°C	0.09	0.15		0.09	0.15		
	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 500\ \mu\text{A}$	Full range	0.15			0.15			
		25°C	0.2	0.3		0.2	0.3		
$A_{VD}$ Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}$ , $V_O = 1\text{ V to }4\text{ V}$	$R_L = 50\ \text{k}\Omega$ ‡	25°C	80	170		80	170	V/mV
			Full range	50			50		
		$R_L = 1\ \text{M}\Omega$ ‡	25°C	550			550		
$r_{i(d)}$ Differential input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$
$r_{i(c)}$ Common-mode input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$
$C_{i(c)}$ Common-mode input capacitance	$f = 10\ \text{kHz}$ , P package	25°C	8			8			pF
$z_o$ Closed-loop output impedance	$f = 100\ \text{kHz}$ , $A_V = 10$	25°C	240			240			$\Omega$
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }2.7\text{ V}$ , $V_O = 2.5\text{ V}$ , $R_S = 50\ \Omega$	25°C	70	83		70	83	dB	
		Full range	70			70			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 4.4\text{ V to }8\text{ V}$ , $V_{IC} = V_{DD}/2$ , No load	25°C	80	95		80	95	dB	
		Full range	80			80			

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part,  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLV2262Q and TLV2262M electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted) (continued)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2262Q, TLV2262M			TLV2262AQ, TLV2262AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$I_{DD}$ Supply current	$V_O = 2.5\text{ V}$ , No load	25°C	400	500		400	500	$\mu\text{A}$	
		Full range		500			500		

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part,  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

**TLV2262Q and TLV2262M operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2262Q, TLV2262M			TLV2262AQ, TLV2262AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 0.5\text{ V}$ to $3.5\text{ V}$ , $C_L = 100\text{ pF}^\ddagger$ , $R_L = 50\text{ k}\Omega^\ddagger$	25°C	0.35	0.55		0.35	0.55	$\text{V}/\mu\text{s}$	
		Full range	0.25			0.25			
$V_n$ Equivalent input noise voltage	$f = 10\text{ Hz}$ $f = 1\text{ kHz}$	25°C		40			40	$\text{nV}/\sqrt{\text{Hz}}$	
		25°C		12			12		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz}$ to $1\text{ Hz}$ $f = 0.1\text{ Hz}$ to $10\text{ Hz}$	25°C		0.7			0.7	$\mu\text{V}$	
		25°C		1.3			1.3		
$I_n$ Equivalent input noise current		25°C		0.6			0.6	$\text{fA}/\sqrt{\text{Hz}}$	
THD + N Total harmonic distortion plus noise	$V_O = 0.5\text{ V}$ to $2.5\text{ V}$ , $f = 20\text{ kHz}$ , $R_L = 50\text{ k}\Omega^\ddagger$	25°C		$A_V = 1$		0.017%		0.017%	
				$A_V = 10$		0.03%		0.03%	
Gain-bandwidth product	$f = 50\text{ kHz}$ , $C_L = 100\text{ pF}^\ddagger$ , $R_L = 50\text{ k}\Omega^\ddagger$	25°C		0.71			0.71	MHz	
$B_{OM}$ Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$ , $R_L = 50\text{ k}\Omega^\ddagger$ , $A_V = 1$ , $C_L = 100\text{ pF}^\ddagger$	25°C		185			185	kHz	
$t_s$ Settling time	$A_V = -1$ , Step = $0.5\text{ V}$ to $2.5\text{ V}$ , $R_L = 50\text{ k}\Omega^\ddagger$ , $C_L = 100\text{ pF}^\ddagger$	25°C		To 0.1%		6.4		6.4	$\mu\text{s}$
				To 0.01%		14.1		14.1	
$\phi_m$ Phase margin at unity gain	$R_L = 50\text{ k}\Omega^\ddagger$ , $C_L = 100\text{ pF}^\ddagger$	25°C		56°			56°		
		25°C		11			11		
Gain margin		25°C		11			11	dB	

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part,  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

‡ Referenced to 2.5 V

# TLV226x, TLV226xA Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

**TLV2264Q and TLV2264M electrical characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2264Q, TLV2264M			TLV2264AQ, TLV2264AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage		25°C	300	2500		300	950	$\mu\text{V}$	
		Full range			3000		1500		
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 125°C	2			2			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)	$V_{DD} = \pm 1.5\text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50\ \Omega$	25°C	0.003			0.003			$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	pA	
		125°C			800		800		
$I_{IB}$ Input bias current		25°C	1	60		1	60	pA	
		125°C			800		800		
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$ , $ V_{IO}  \leq 5\text{ mV}$	25°C	0 to 2	-0.3 to 2.2		0 to 2	-0.3 to 2.2	V	
		Full range	0 to 1.7		0 to 1.7				
$V_{OH}$ High-level output voltage	$I_{OH} = -20\ \mu\text{A}$	25°C	2.99			2.99			V
	$I_{OH} = -100\ \mu\text{A}$	25°C	2.85			2.85			
	$I_{OH} = -400\ \mu\text{A}$	Full range	2.82			2.82			
		25°C	2.7			2.7			
$V_{OL}$ Low-level output voltage	$V_{IC} = 1.5\text{ V}$ , $I_{OL} = 50\ \mu\text{A}$	25°C	10			10			mV
	$V_{IC} = 1.5\text{ V}$ , $I_{OL} = 500\ \mu\text{A}$	25°C	100	150		100	150		
		Full range			150		150		
	$V_{IC} = 1.5\text{ V}$ , $I_{OL} = 1\text{ mA}$	25°C	200	300		200	300		
Full range				300		300			
$AVD$ Large-signal differential voltage amplification	$V_{IC} = 1.5\text{ V}$ , $V_O = 1\text{ V to }2\text{ V}$	$R_L = 50\ \text{k}\Omega$ ‡	25°C	60	100		60	100	V/mV
			Full range	25			25		
		$R_L = 1\ \text{M}\Omega$ ‡	25°C	100			100		
$r_{i(d)}$ Differential input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$
$r_{i(c)}$ Common-mode input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$
$c_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$ , N package	25°C	8			8			pF
$z_o$ Closed-loop output impedance	$f = 100\text{ kHz}$ , $A_V = 10$	25°C	270			270			$\Omega$
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }1.7\text{ V}$ , $V_O = 1.5\text{ V}$ , $R_S = 50\ \Omega$	25°C	65	75		65	77	dB	
		Full range	60			60			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 2.7\text{ V to }8\text{ V}$ , $V_{IC} = V_{DD}/2$ , No load	25°C	80	95		80	100	dB	
		Full range	80			80			

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part,  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

‡ Referenced to 1.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLV226x, TLV226xA**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

**TLV2264Q and TLV2264M electrical characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$  (unless otherwise noted) (continued)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2264Q, TLV2264M			TLV2264AQ, TLV2264AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$I_{DD}$	Supply current (four amplifiers) $V_O = 1.5\text{ V}$ , No load	25°C	0.8		1	0.8		1	mA
		Full range						1	

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part,  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

**TLV2264Q and TLV2264M operating characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2264Q, TLV2264M			TLV2264AQ, TLV2264AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain $V_O = 0.5\text{ V}$ to $1.7\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C	0.35	0.55		0.35	0.55		$\text{V}/\mu\text{s}$
		Full range	0.25			0.25			
$V_n$	Equivalent input noise voltage	$f = 10\text{ Hz}$	25°C			43			$\text{nV}/\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$	25°C			12			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz}$ to $1\text{ Hz}$	25°C			0.6			$\mu\text{V}$
		$f = 0.1\text{ Hz}$ to $10\text{ Hz}$	25°C			1			
$I_n$	Equivalent input noise current	25°C	0.6			0.6			$\text{fA}/\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise $V_O = 0.5\text{ V}$ to $2.5\text{ V}$ , $f = 20\text{ kHz}$ , $R_L = 50\text{ k}\Omega$ ‡	$A_V = 1$	25°C			0.03%			
		$A_V = 10$	25°C			0.05%			
	Gain-bandwidth product $f = 1\text{ kHz}$ , $C_L = 100\text{ pF}$ ‡	$R_L = 50\text{ k}\Omega$ ‡	25°C			0.67			MHz
$B_{OM}$	Maximum output-swing bandwidth $V_{O(PP)} = 1\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡	$A_V = 1$ , $C_L = 100\text{ pF}$ ‡	25°C			395			kHz
$t_s$	Settling time $A_V = -1$ , Step = $1\text{ V}$ to $2\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	$T_o = 0.1\%$	25°C			5.6			$\mu\text{s}$
		$T_o = 0.01\%$	25°C			12.5			
$\phi_m$	Phase margin at unity gain $R_L = 50\text{ k}\Omega$ ‡	$C_L = 100\text{ pF}$ ‡	25°C			55°			
			25°C			11			
	Gain margin		25°C			11			dB

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part,  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

‡ Referenced to  $1.5\text{ V}$

# TLV226x, TLV226xA Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

**TLV2264Q and TLV2264M electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2264Q, TLV2264M			TLV2264AQ, TLV2264AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{DD} \pm = \pm 2.5\text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50\ \Omega$	25°C	300 2500		300 950		$\mu\text{V}$		
		Full range	3000		1500				
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 125°C	2		2		$\mu\text{V}/^\circ\text{C}$		
Input offset voltage long-term drift (see Note 4)		25°C	0.003		0.003		$\mu\text{V}/\text{mo}$		
$I_{IO}$ Input offset current		25°C	0.5	60	0.5	60	pA		
		125°C	800		800				
$I_{IB}$ Input bias current		25°C	1	60	1	60	pA		
		125°C	800		800				
$V_{ICR}$ Common-mode input voltage range	$ V_{IO}  \leq 5\text{ mV}$ , $R_S = 50\ \Omega$	25°C	0 to 4	-0.3 to 4.2	0 to 4	-0.3 to 4.2	V		
		Full range	0 to 3.5		0 to 3.5				
$V_{OH}$ High-level output voltage	$I_{OH} = -20\ \mu\text{A}$ $I_{OH} = -100\ \mu\text{A}$ $I_{OH} = -400\ \mu\text{A}$	25°C	4.99		4.99		V		
		25°C	4.85	4.94	4.85	4.94			
		Full range	4.82		4.82				
		25°C	4.7	4.85	4.7	4.85			
$V_{OL}$ Low-level output voltage	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 50\ \mu\text{A}$ $V_{IC} = 2.5\text{ V}$ , $I_{OL} = 500\ \mu\text{A}$ $V_{IC} = 2.5\text{ V}$ , $I_{OL} = 1\text{ mA}$	25°C	0.01		0.01		V		
		25°C	0.09	0.15	0.09	0.15			
		Full range	0.15		0.15				
		25°C	0.2	0.3	0.2	0.3			
$AVD$ Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}$ , $V_O = 1\text{ V to }4\text{ V}$	$R_L = 50\ \text{k}\Omega$ ‡ $R_L = 1\ \text{M}\Omega$ ‡	25°C	80	170	80	170	V/mV	
			Full range	50		50			
			25°C	550		550			
$r_{i(d)}$ Differential input resistance		25°C	$10^{12}$		$10^{12}$		$\Omega$		
$r_{i(c)}$ Common-mode input resistance		25°C	$10^{12}$		$10^{12}$		$\Omega$		
$C_{i(c)}$ Common-mode input capacitance	$f = 10\ \text{kHz}$ , N package	25°C	8		8		pF		
$z_o$ Closed-loop output impedance	$f = 100\ \text{kHz}$ , $A_V = 10$	25°C	240		240		$\Omega$		
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }2.7\text{ V}$ , $V_O = 2.5\text{ V}$ , $R_S = 50\ \Omega$	25°C	70	83	70	83	dB		
		Full range	70		70				
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 4.4\text{ V to }8\text{ V}$ , $V_{IC} = V_{DD}/2$ , No load	25°C	80	95	80	95	dB		
		Full range	80		80				

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part,  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLV226x, TLV226xA**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

**TLV2264Q and TLV2264M electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted) (continued)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2264Q, TLV2264M			TLV2264AQ, TLV2264AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$I_{DD}$	Supply current (four amplifiers) $V_O = 2.5\text{ V}$ , No load	25°C	0.8		1	0.8		1	mA
		Full range			1			1	

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part,  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

**TLV2264Q and TLV2264M operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLV2264Q, TLV2264M			TLV2264AQ, TLV2264AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain $V_O = 0.5\text{ V}$ to $3.5\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C	0.35	0.55		0.35	0.55		V/ $\mu\text{s}$
		Full range	0.25			0.25			
$V_n$	Equivalent input noise voltage	$f = 10\text{ Hz}$	40			40			nV/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$	12			12			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz}$ to $1\text{ Hz}$	0.7			0.7			$\mu\text{V}$
		$f = 0.1\text{ Hz}$ to $10\text{ Hz}$	1.3			1.3			
$I_n$	Equivalent input noise current	25°C	0.6			0.6			fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise $V_O = 0.5\text{ V}$ to $2.5\text{ V}$ , $f = 20\text{ kHz}$ , $R_L = 50\text{ k}\Omega$ ‡	$A_V = 1$	0.017%			0.017%			
		$A_V = 10$	0.03%			0.03%			
	Gain-bandwidth product $f = 50\text{ kHz}$ , $C_L = 100\text{ pF}$ ‡	$R_L = 50\text{ k}\Omega$ ‡, 25°C	0.71			0.71			MHz
BOM	Maximum output-swing bandwidth $V_{O(PP)} = 2\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $A_V = 1$ , $C_L = 100\text{ pF}$ ‡	25°C	185			185			kHz
$t_s$	Settling time $A_V = -1$ , Step = $0.5\text{ V}$ to $2.5\text{ V}$ , $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	$T_o$ 0.1%	6.4			6.4			$\mu\text{s}$
		$T_o$ 0.01%	14.1			14.1			
$\phi_m$	Phase margin at unity gain $R_L = 50\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C	56°			56°			
		25°C	11			11			

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part,  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

‡ Referenced to  $2.5\text{ V}$



**TLV226x, TLV226xA**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SLOS186C – FEBRUARY 1997 – REVISED AUGUST 2006

**TYPICAL CHARACTERISTICS**

**Table of Graphs**

		<b>FIGURE</b>
$V_{IO}$	Input offset voltage	Distribution vs Common-mode voltage 2 – 5 6, 7
$\alpha V_{IO}$	Input offset voltage temperature coefficient	Distribution 8 – 11
$I_{IB}/I_{IO}$	Input bias and input offset currents	vs Free-air temperature 12
$V_I$	Input voltage	vs Supply voltage vs Free-air temperature 13 14
$V_{OH}$	High-level output voltage	vs High-level output current 15, 18
$V_{OL}$	Low-level output voltage	vs Low-level output current 16, 17, 19
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency 20
$I_{OS}$	Short-circuit output current	vs Supply voltage vs Free-air temperature 21 22
$V_{ID}$	Differential input voltage	vs Output voltage 23, 24
$A_{VD}$	Differential voltage amplification	vs Load resistance 25
$A_{VD}$	Large-signal differential voltage amplification	vs Frequency vs Free-air temperature 26, 27 28, 29
$z_o$	Output impedance	vs Frequency 30, 31
$CMRR$	Common-mode rejection ratio	vs Frequency vs Free-air temperature 32 33
$k_{SVR}$	Supply-voltage rejection ratio	vs Frequency vs Free-air temperature 34, 35 36, 37
$I_{DD}$	Supply current	vs Free-air temperature 38, 39
$SR$	Slew rate	vs Load capacitance vs Free-air temperature 40 41
$V_O$	Inverting large-signal pulse response	42, 43
$V_O$	Voltage-follower large-signal pulse response	44, 45
$V_O$	Inverting small-signal pulse response	46, 47
$V_O$	Voltage-follower small-signal pulse response	48, 49
$V_n$	Equivalent input noise voltage	vs Frequency 50, 51
	Input noise voltage	Over a 10-second period 52
	Integrated noise voltage	vs Frequency 53
$THD + N$	Total harmonic distortion plus noise	vs Frequency 54
	Gain-bandwidth product	vs Supply voltage vs Free-air temperature 55 56
$\phi_m$	Phase margin	vs Frequency vs Load capacitance 26, 27 57
	Gain margin	vs Load capacitance 58
$B_1$	Unity-gain bandwidth	vs Load capacitance 59
	Overestimation of phase margin	vs Load capacitance 60

TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLV2262  
 INPUT OFFSET VOLTAGE

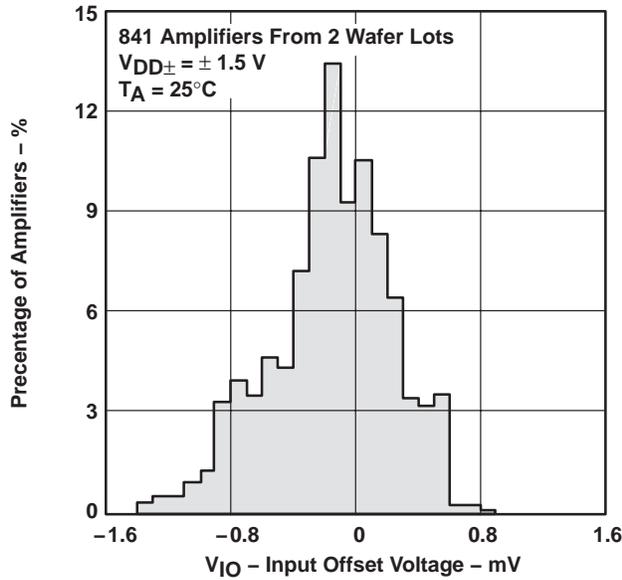


Figure 2

DISTRIBUTION OF TLV2262  
 INPUT OFFSET VOLTAGE

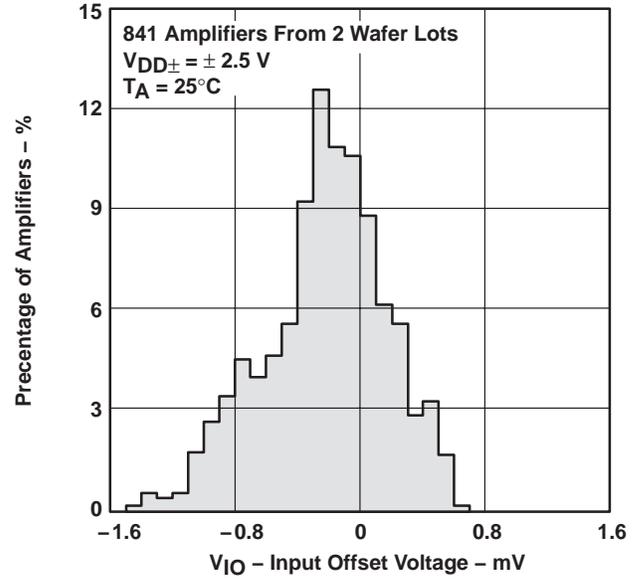


Figure 3

DISTRIBUTION OF TLV2264  
 INPUT OFFSET VOLTAGE

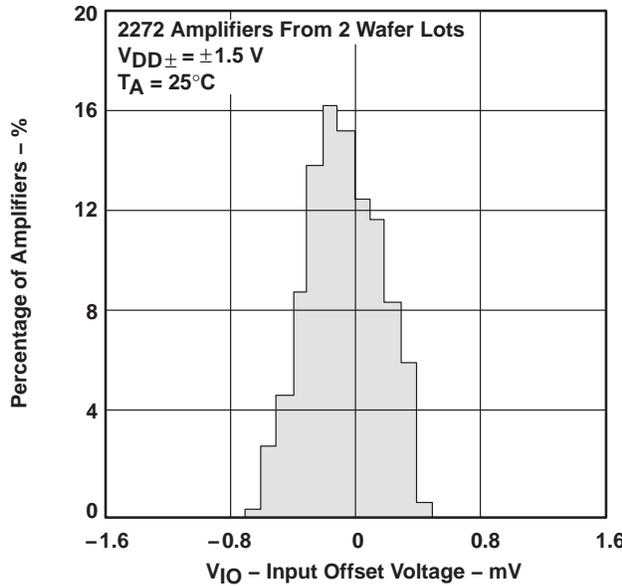


Figure 4

DISTRIBUTION OF TLV2264  
 INPUT OFFSET VOLTAGE

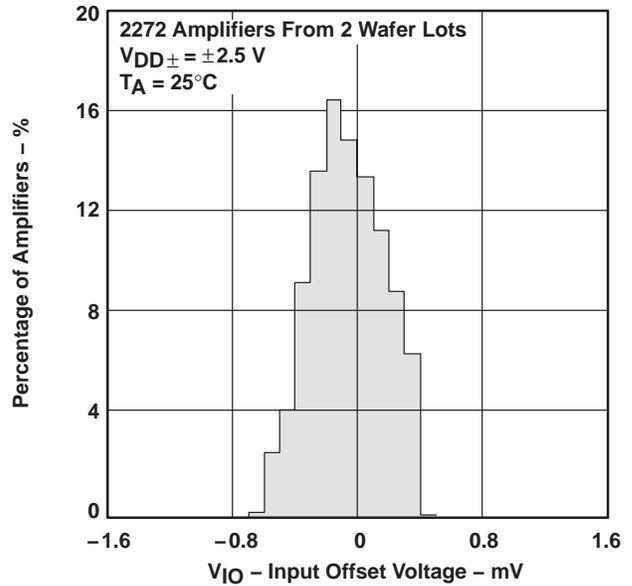
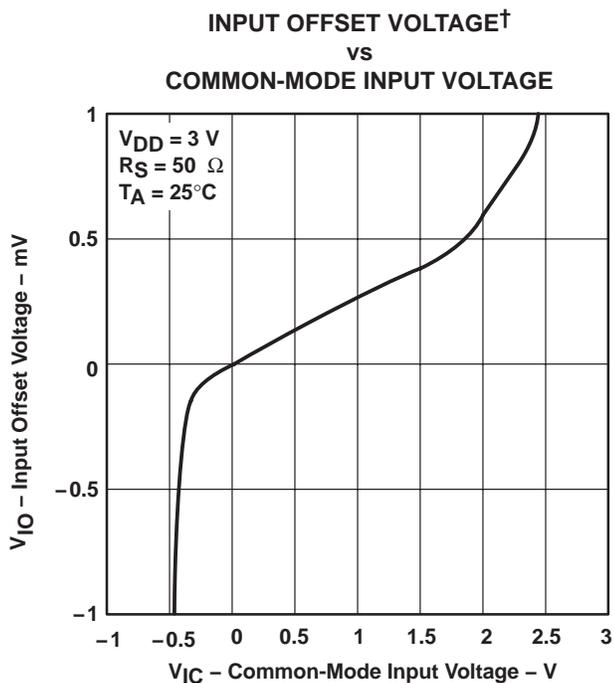
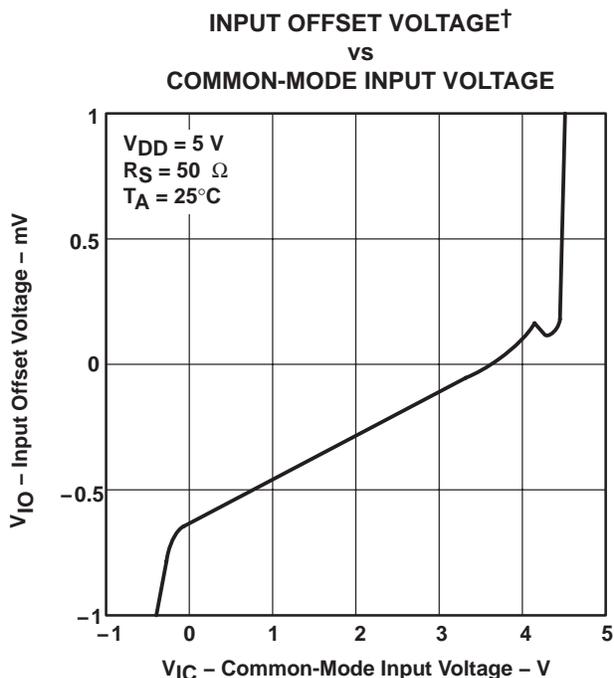


Figure 5

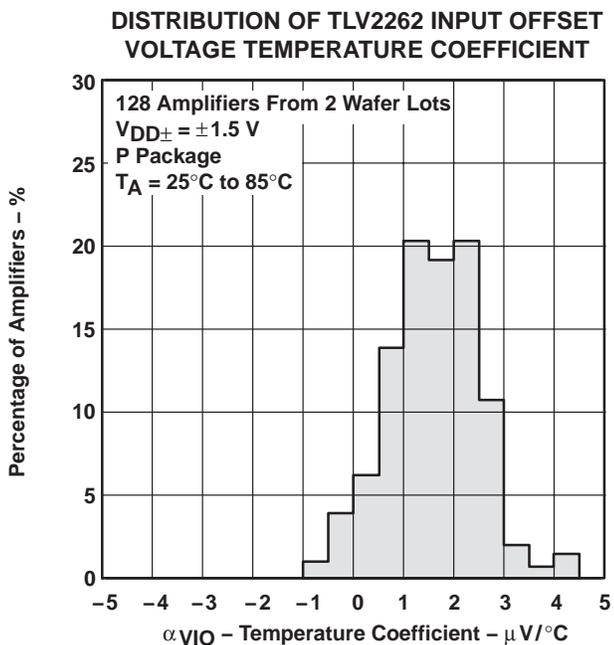
**TYPICAL CHARACTERISTICS**



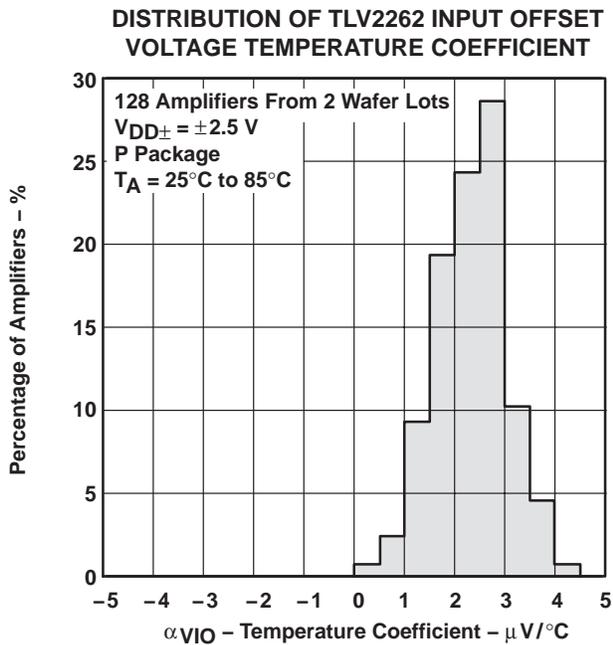
**Figure 6**



**Figure 7**



**Figure 8**



**Figure 9**

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

TYPICAL CHARACTERISTICS

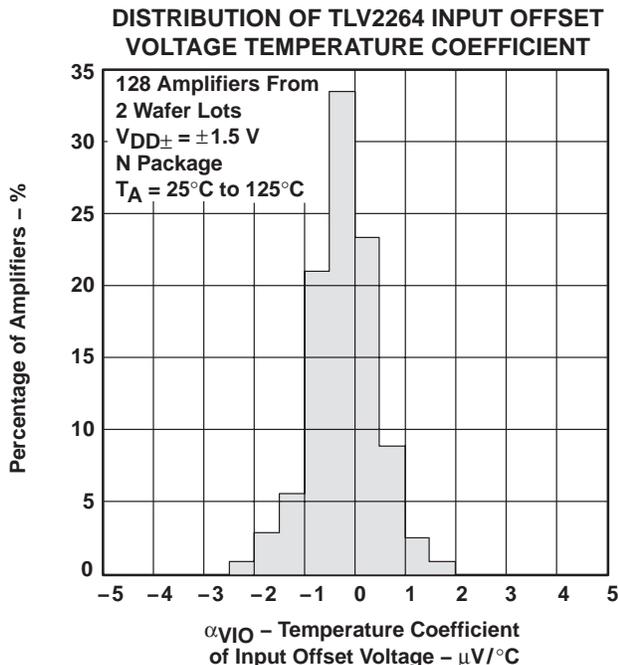


Figure 10

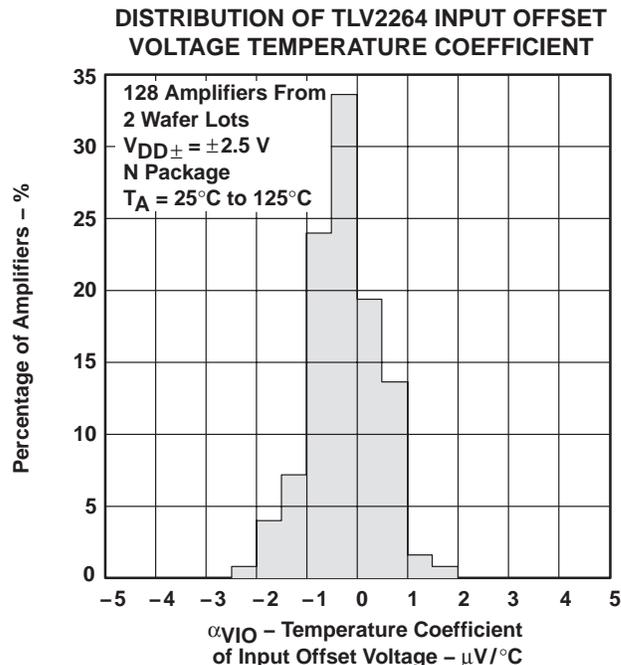


Figure 11

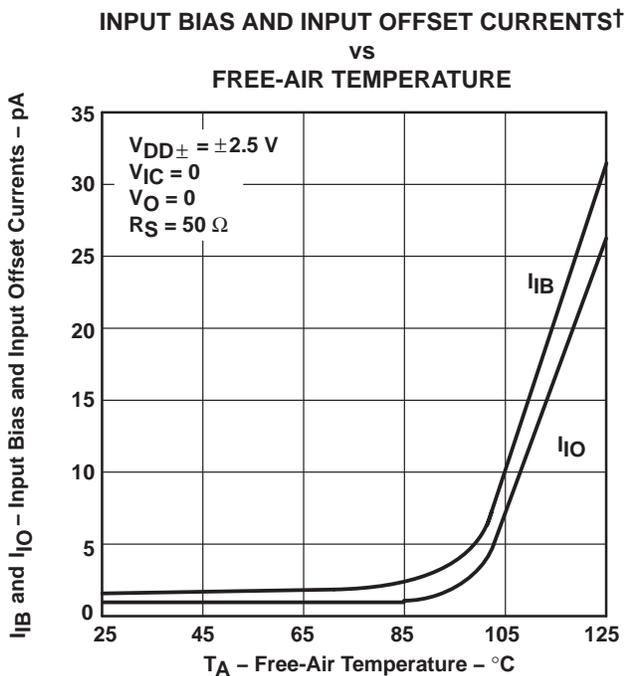


Figure 12

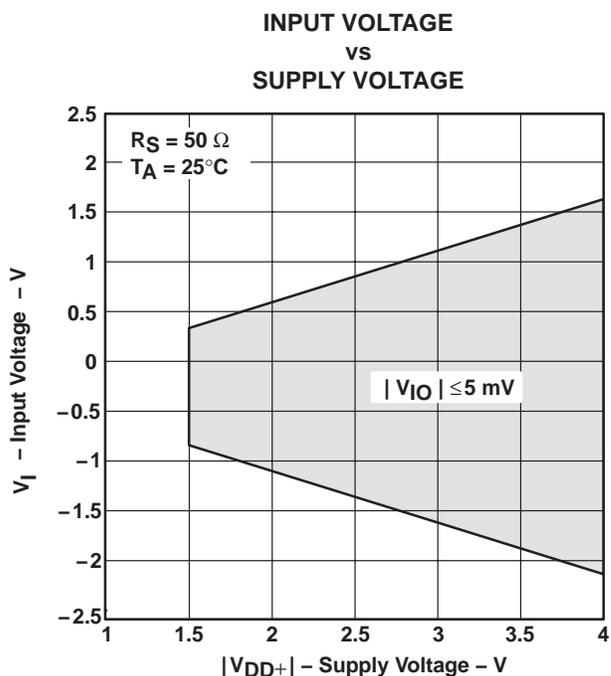
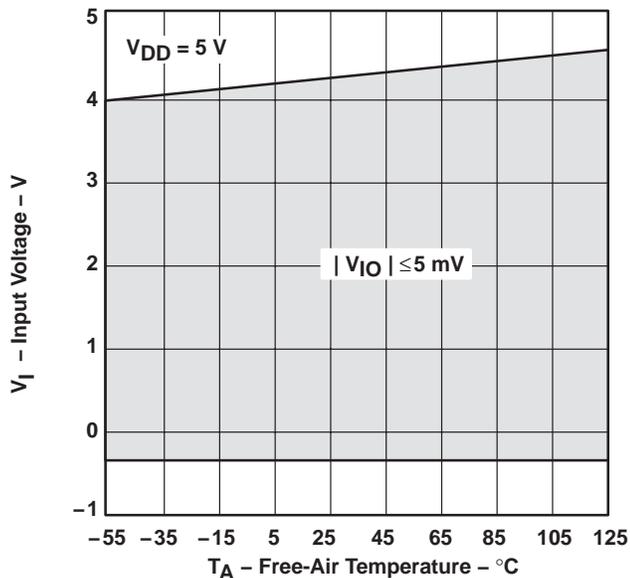


Figure 13

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

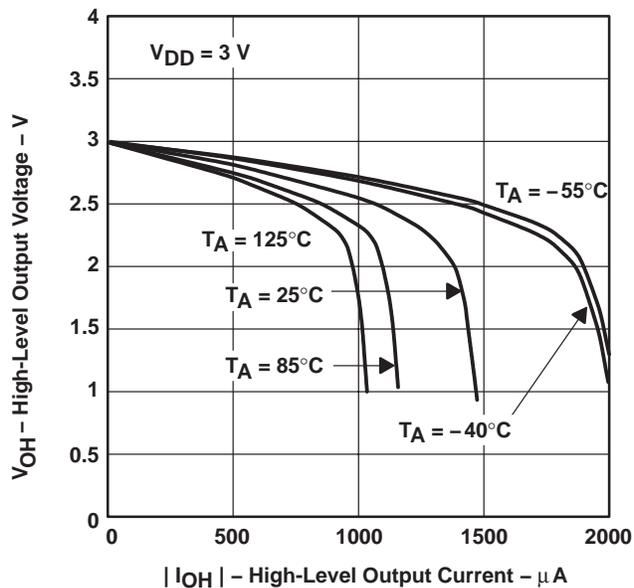
**TYPICAL CHARACTERISTICS**

**INPUT VOLTAGE†‡**  
**vs**  
**FREE-AIR TEMPERATURE**



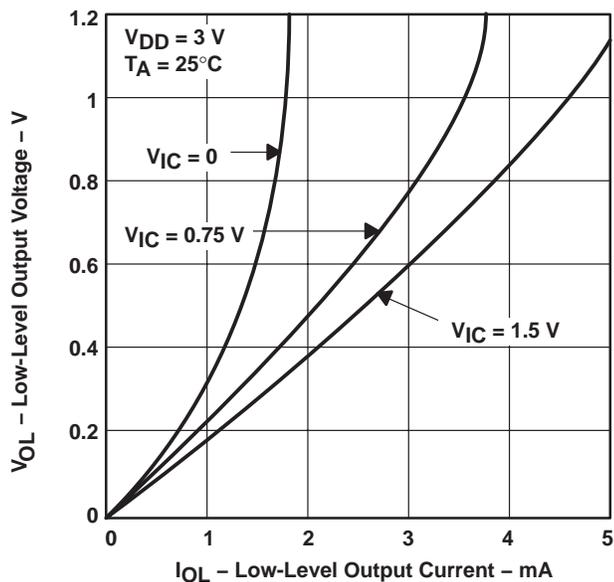
**Figure 14**

**HIGH-LEVEL OUTPUT VOLTAGE†‡**  
**vs**  
**HIGH-LEVEL OUTPUT CURRENT**



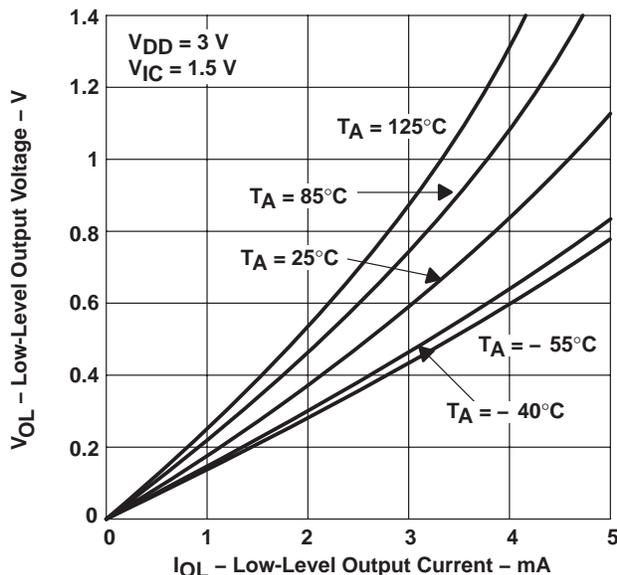
**Figure 15**

**LOW-LEVEL OUTPUT VOLTAGE†**  
**vs**  
**LOW-LEVEL OUTPUT CURRENT**



**Figure 16**

**LOW-LEVEL OUTPUT VOLTAGE†‡**  
**vs**  
**LOW-LEVEL OUTPUT CURRENT**



**Figure 17**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.  
 ‡ For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

TYPICAL CHARACTERISTICS

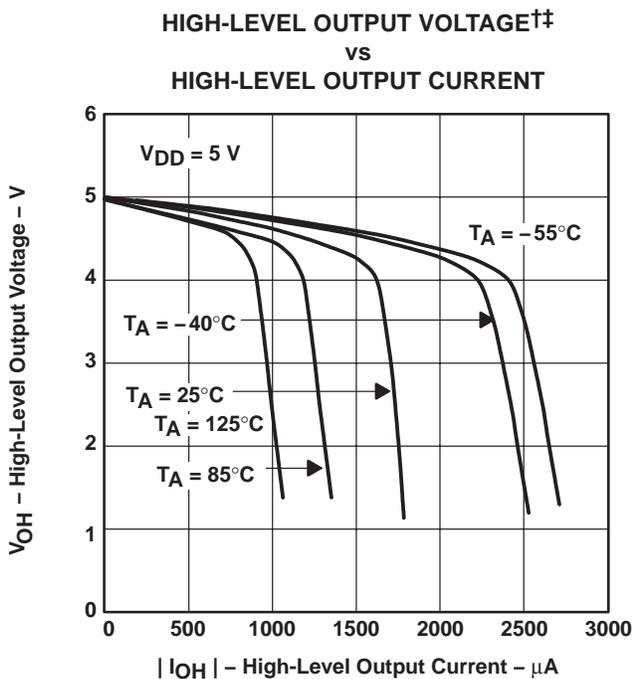


Figure 18

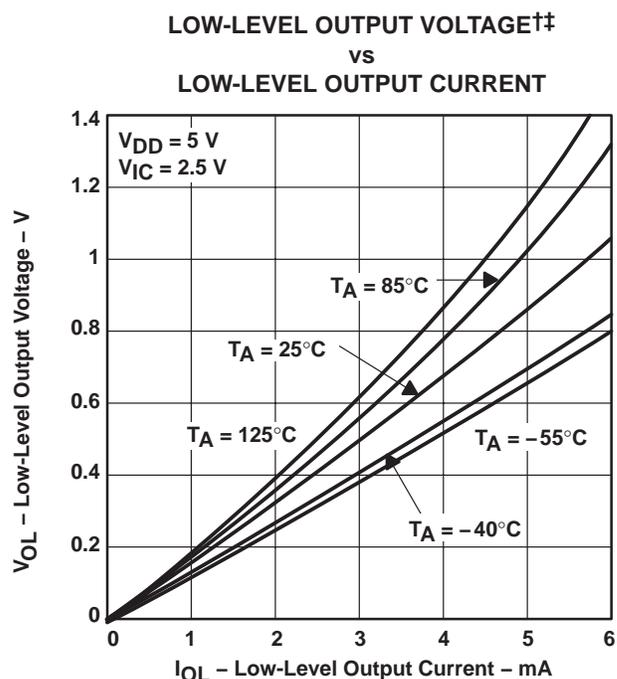


Figure 19

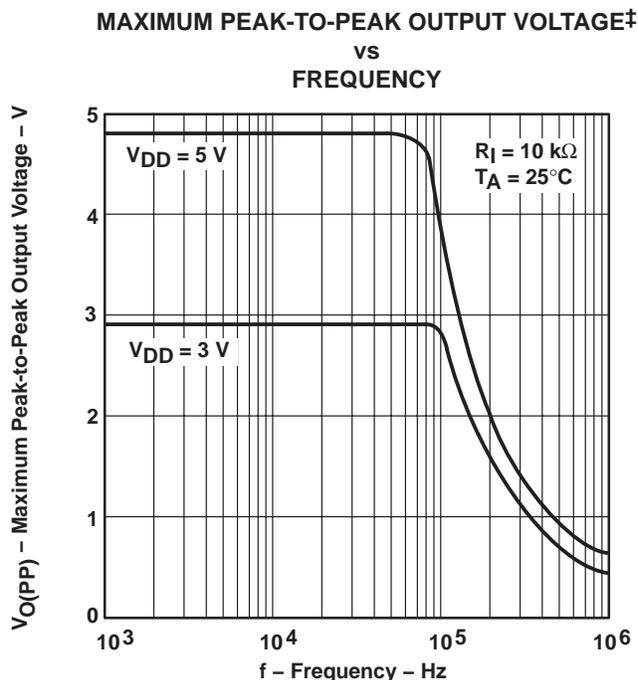


Figure 20

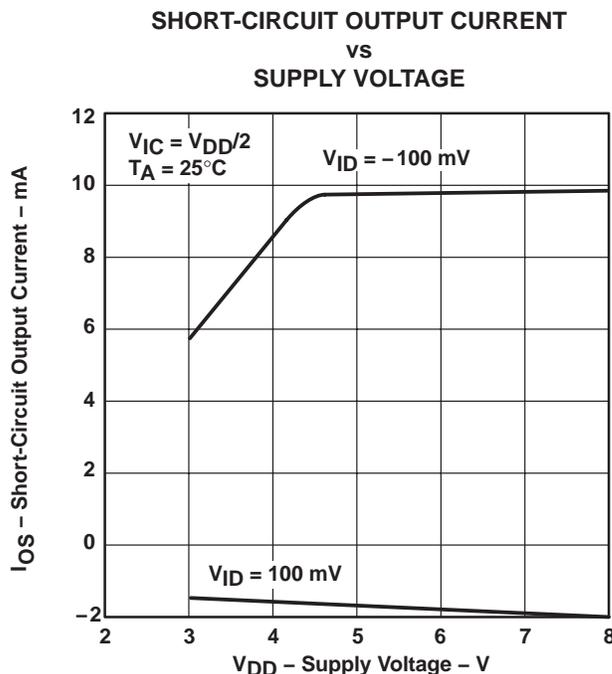
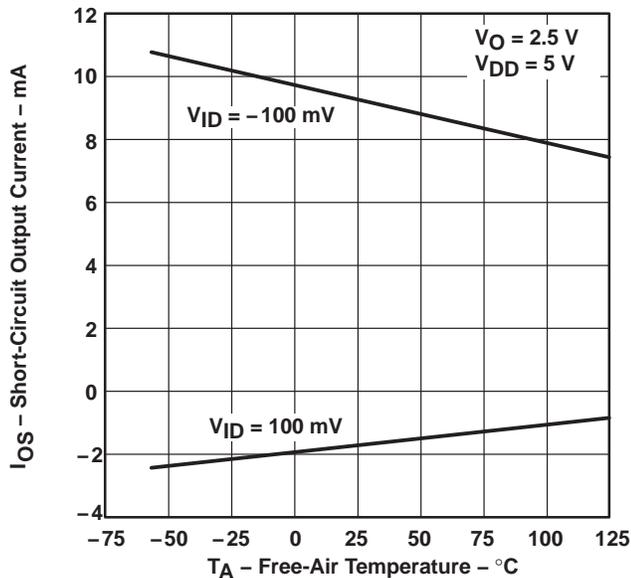


Figure 21

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.  
‡ For all curves where  $V_{DD} = 5 V$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3 V$ , all loads are referenced to 1.5 V.

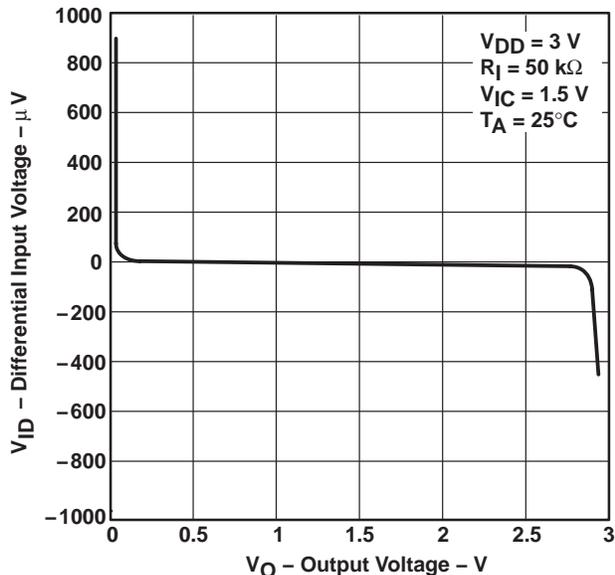
**TYPICAL CHARACTERISTICS**

**SHORT-CIRCUIT OUTPUT CURRENT†**  
**vs**  
**FREE-AIR TEMPERATURE**



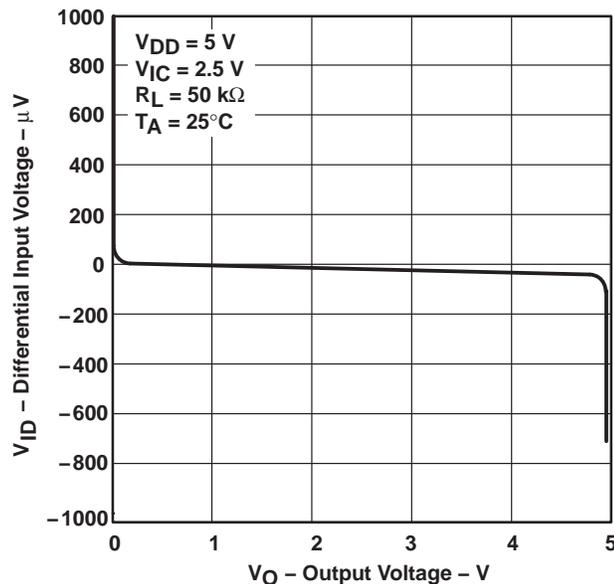
**Figure 22**

**DIFFERENTIAL INPUT VOLTAGE‡**  
**vs**  
**OUTPUT VOLTAGE**



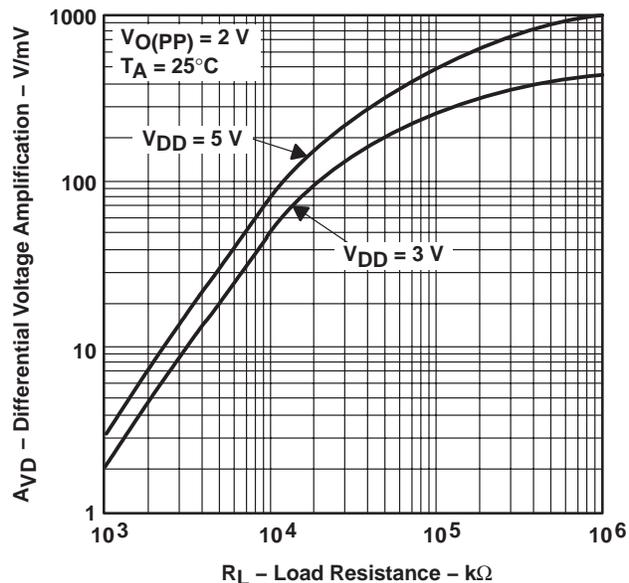
**Figure 23**

**DIFFERENTIAL INPUT VOLTAGE‡**  
**vs**  
**OUTPUT VOLTAGE**



**Figure 24**

**DIFFERENTIAL VOLTAGE AMPLIFICATION‡**  
**vs**  
**LOAD RESISTANCE**



**Figure 25**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE  
 AMPLIFICATION AND PHASE MARGIN†  
 vs  
 FREQUENCY

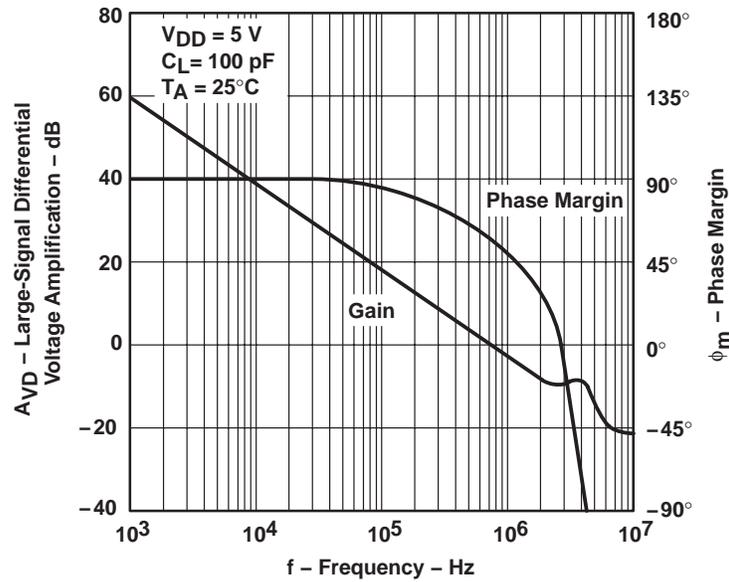


Figure 26

LARGE-SIGNAL DIFFERENTIAL VOLTAGE  
 AMPLIFICATION AND PHASE MARGIN†  
 vs  
 FREQUENCY

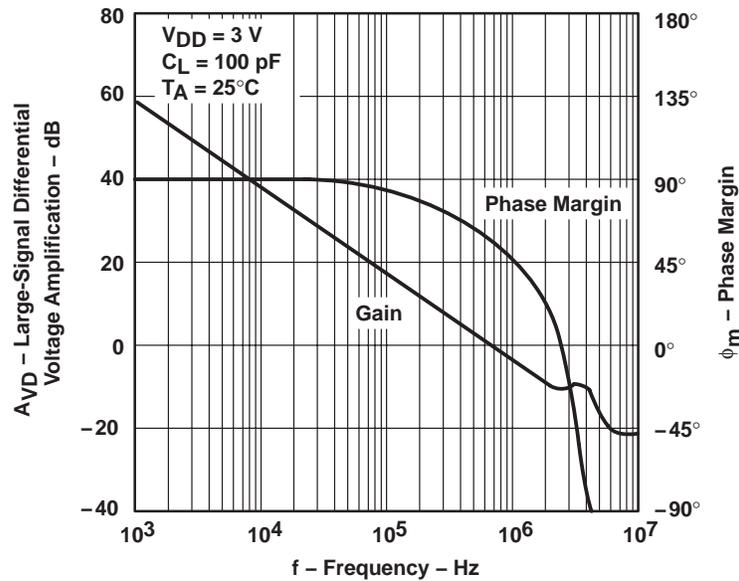
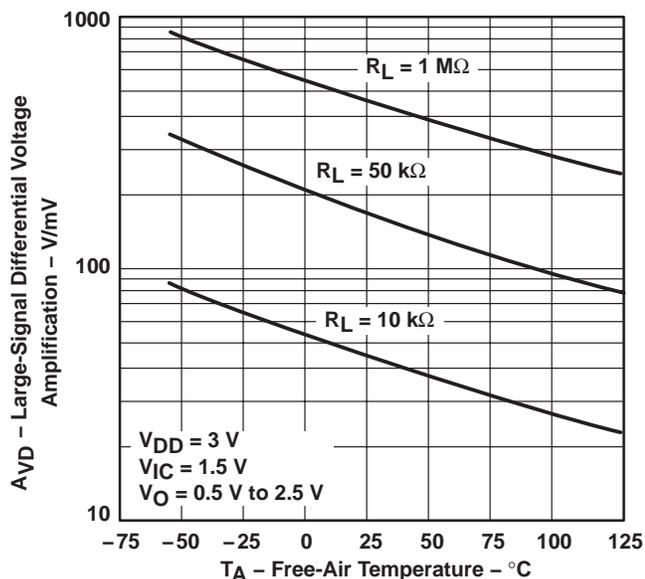


Figure 27

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

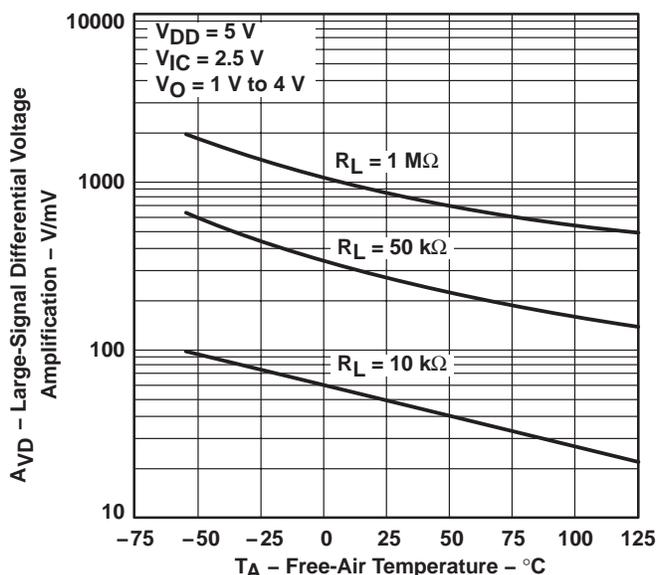
**TYPICAL CHARACTERISTICS**

**LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION†‡**  
**vs**  
**FREE-AIR TEMPERATURE**



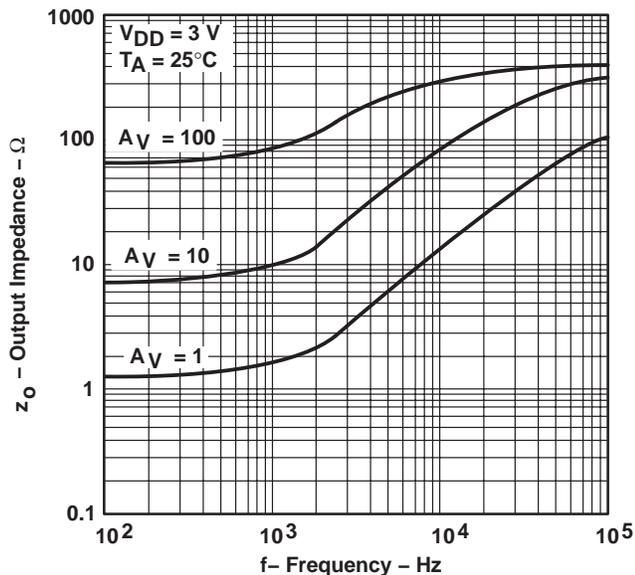
**Figure 28**

**LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION†‡**  
**vs**  
**FREE-AIR TEMPERATURE**



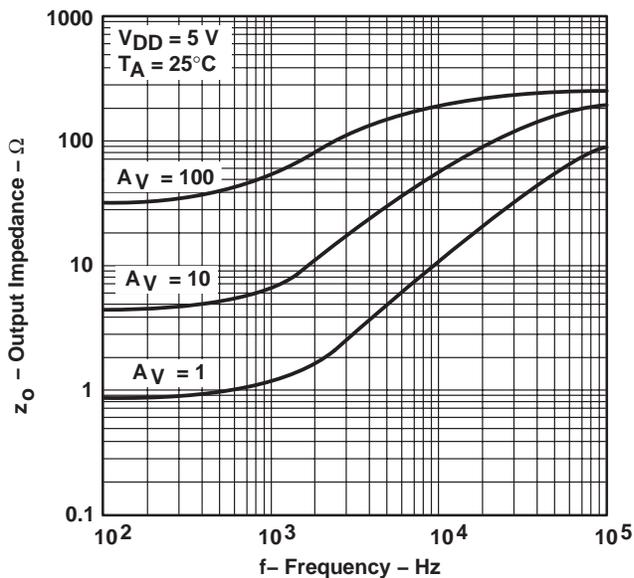
**Figure 29**

**OUTPUT IMPEDANCE‡**  
**vs**  
**FREQUENCY**



**Figure 30**

**OUTPUT IMPEDANCE‡**  
**vs**  
**FREQUENCY**



**Figure 31**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

TYPICAL CHARACTERISTICS

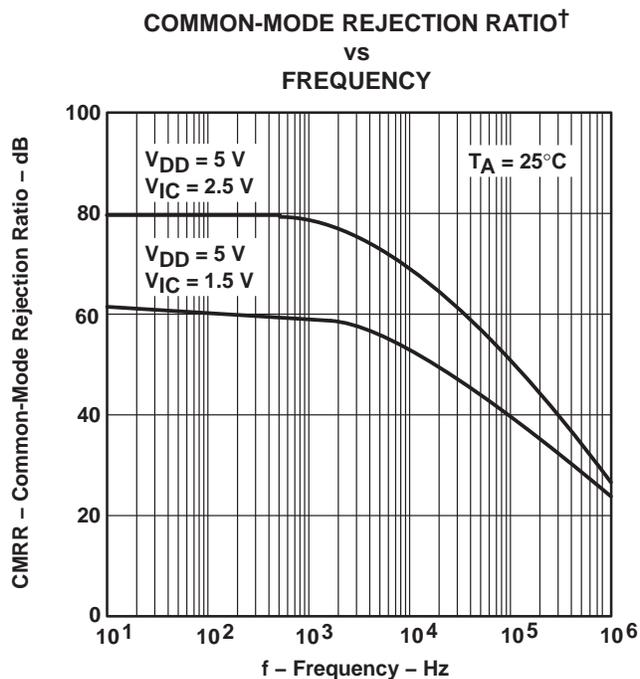


Figure 32

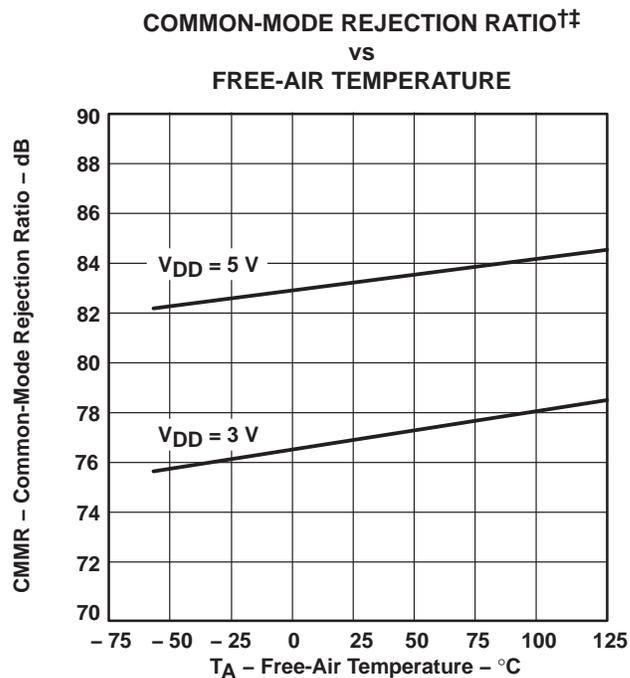


Figure 33

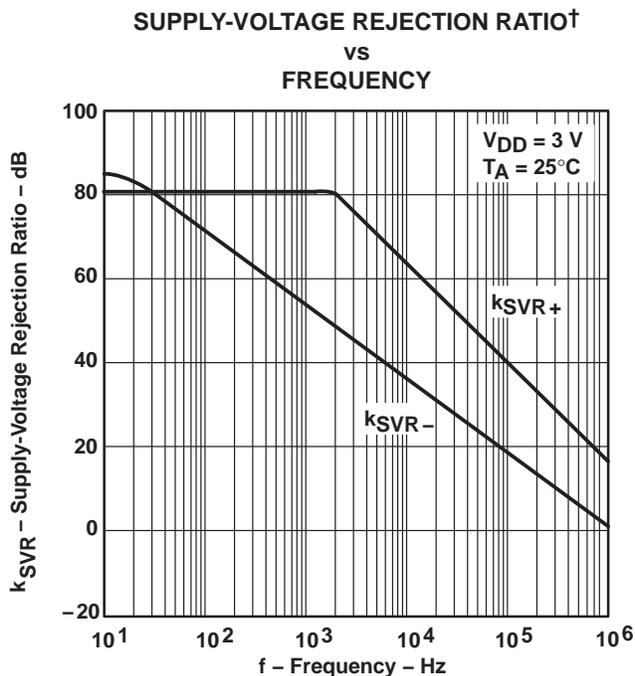


Figure 34

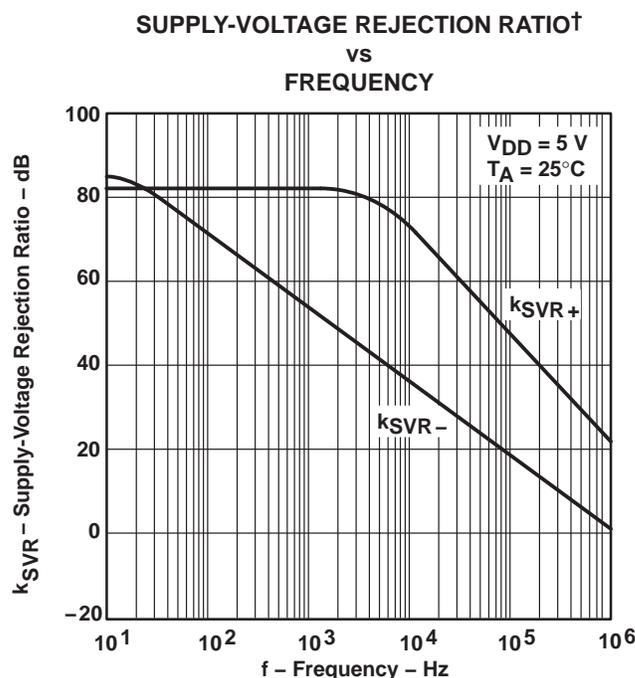
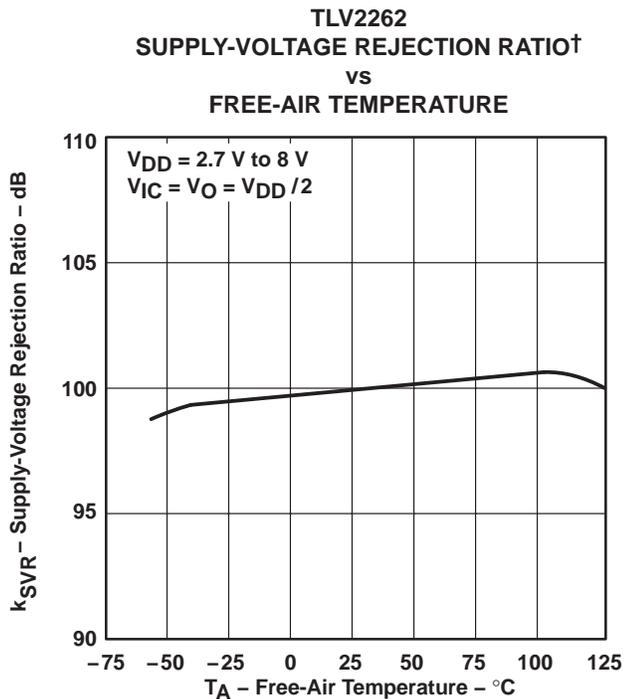


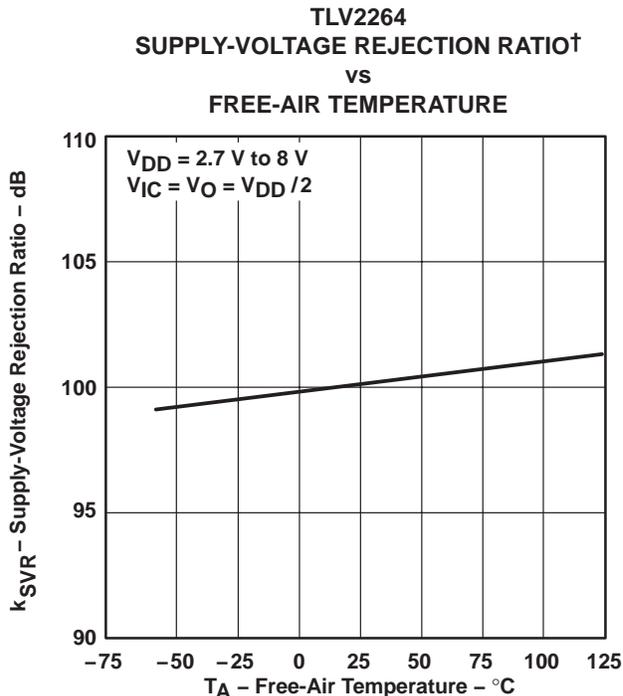
Figure 35

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.  
 ‡ Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

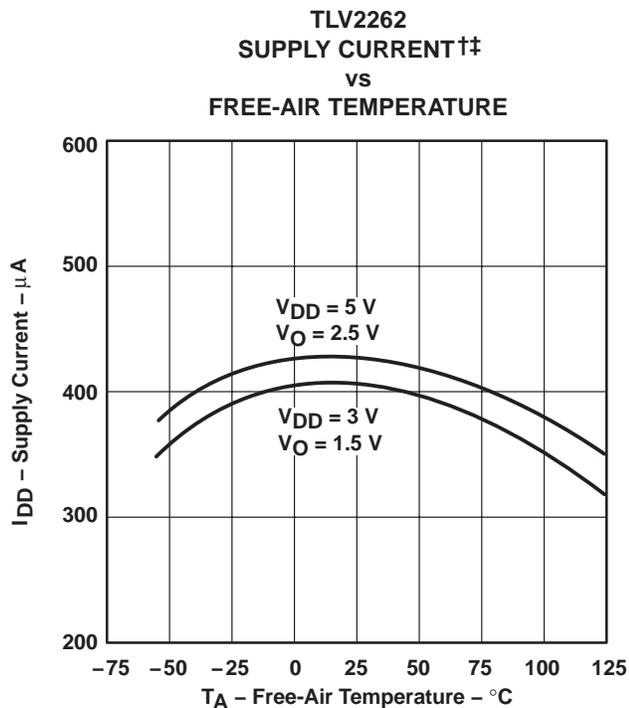
**TYPICAL CHARACTERISTICS**



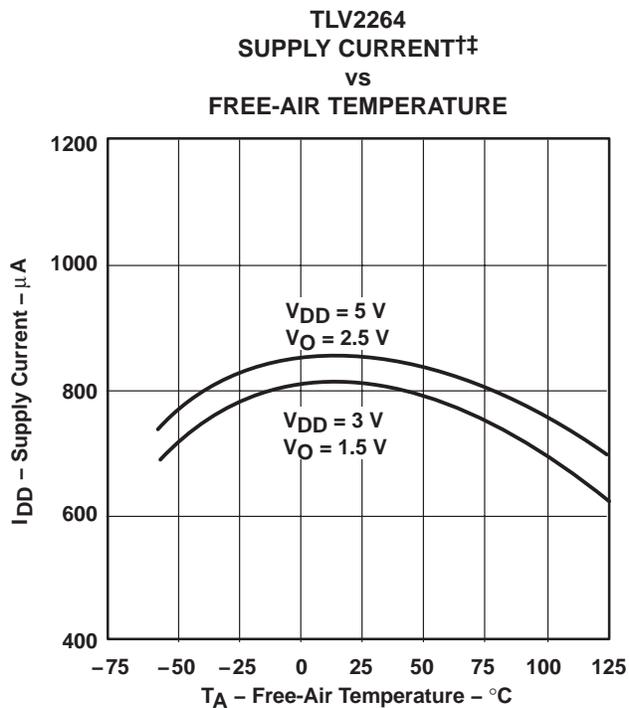
**Figure 36**



**Figure 37**



**Figure 38**

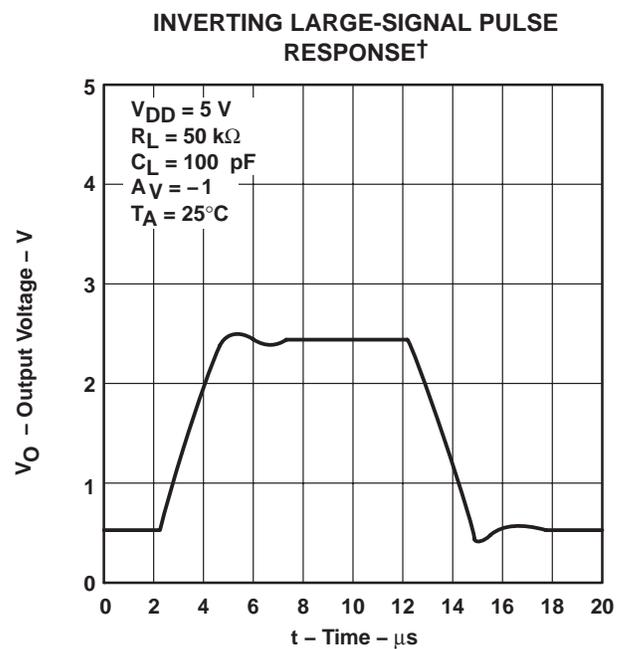
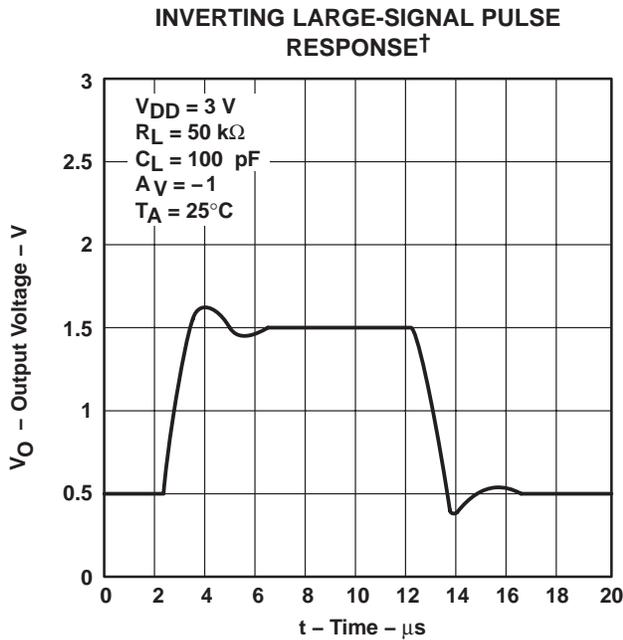
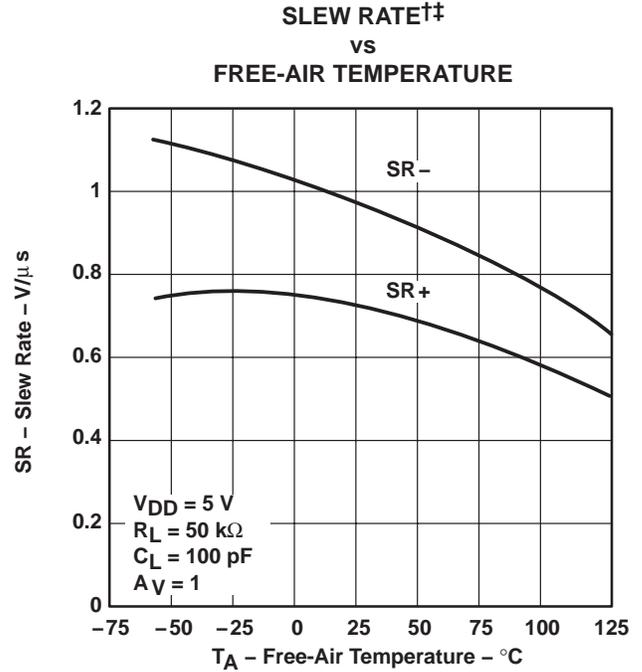
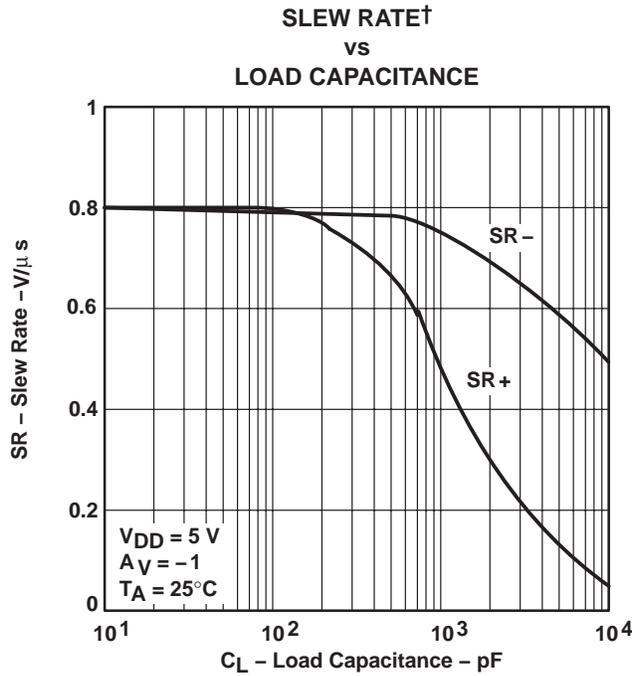


**Figure 39**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For all curves where  $V_{DD} = 5 \text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3 \text{ V}$ , all loads are referenced to 1.5 V.

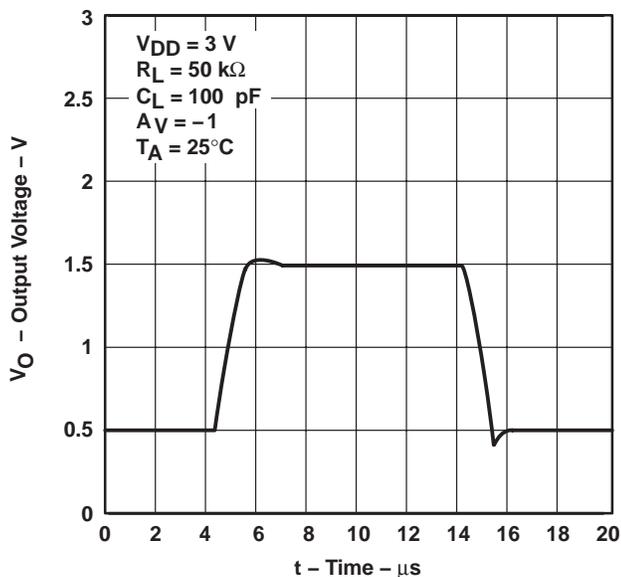
TYPICAL CHARACTERISTICS



† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.  
 ‡ Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

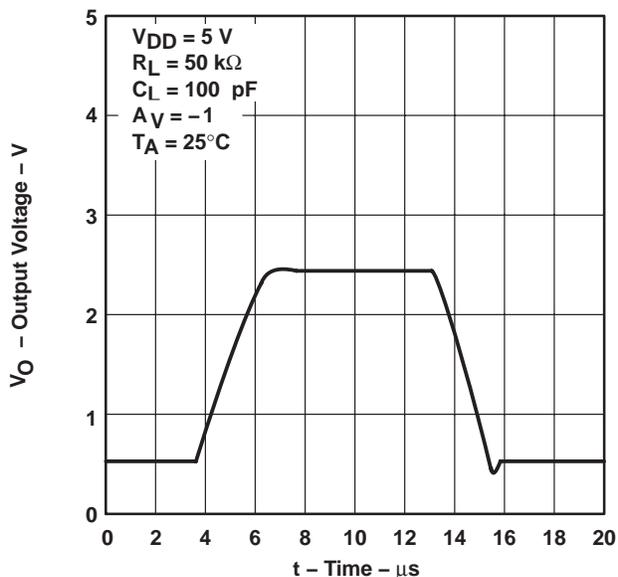
**TYPICAL CHARACTERISTICS**

**VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE†**



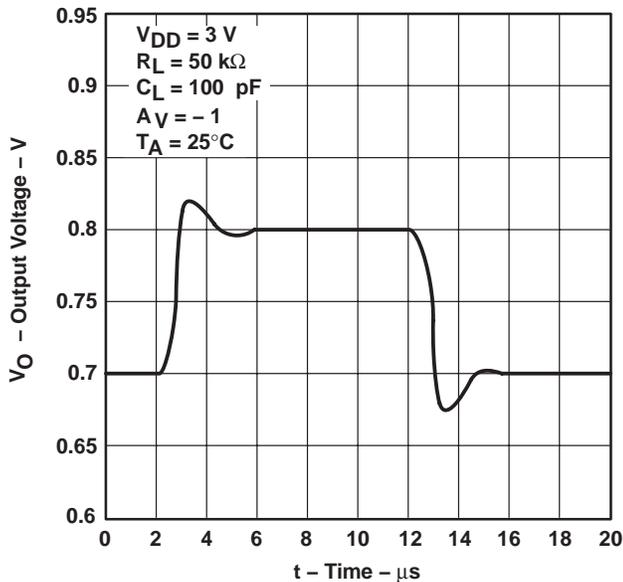
**Figure 44**

**VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE†**



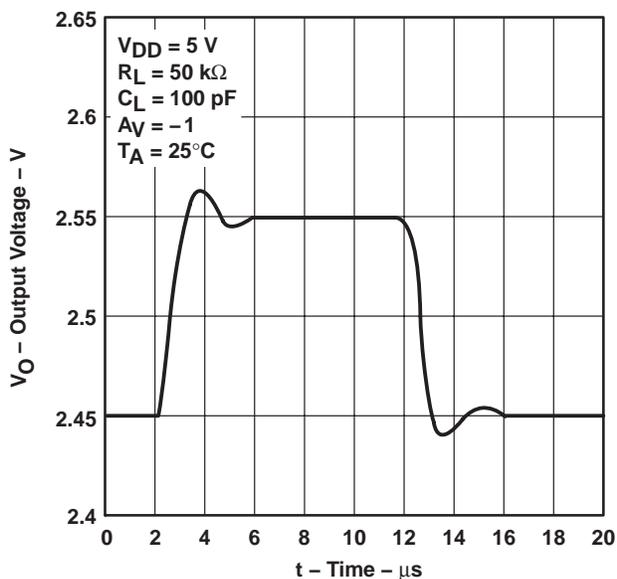
**Figure 45**

**INVERTING SMALL-SIGNAL PULSE RESPONSE†**



**Figure 46**

**INVERTING SMALL-SIGNAL PULSE RESPONSE†**



**Figure 47**

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

TYPICAL CHARACTERISTICS

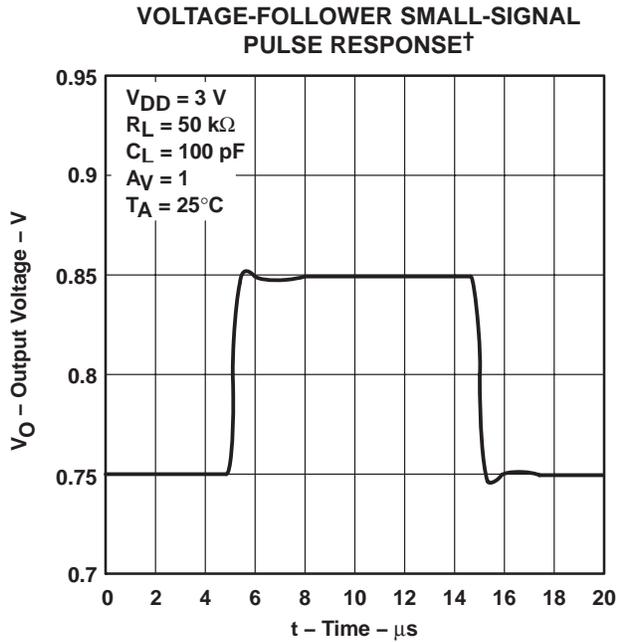


Figure 48

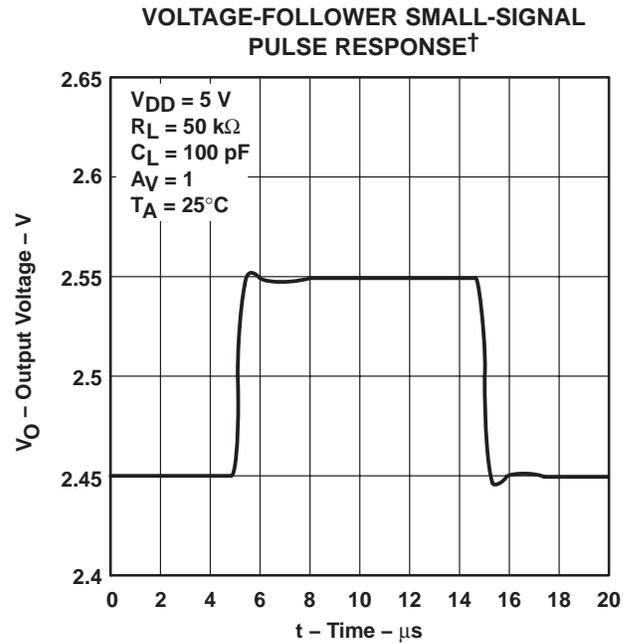


Figure 49

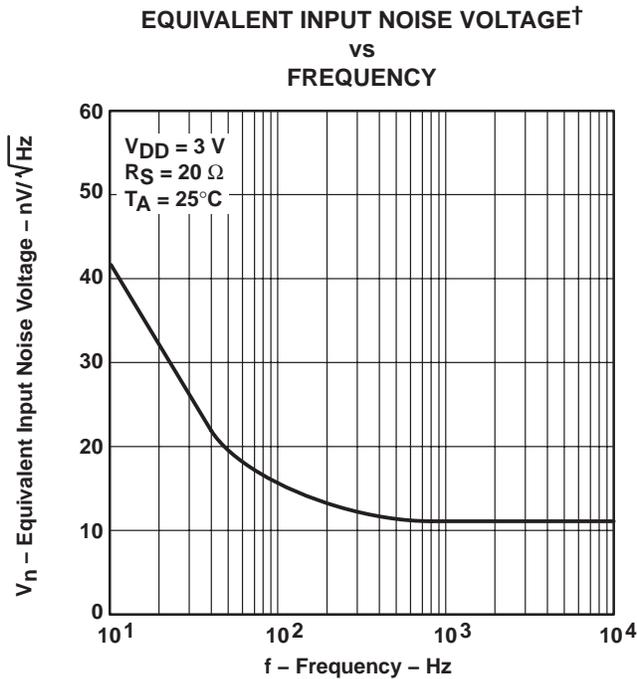


Figure 50

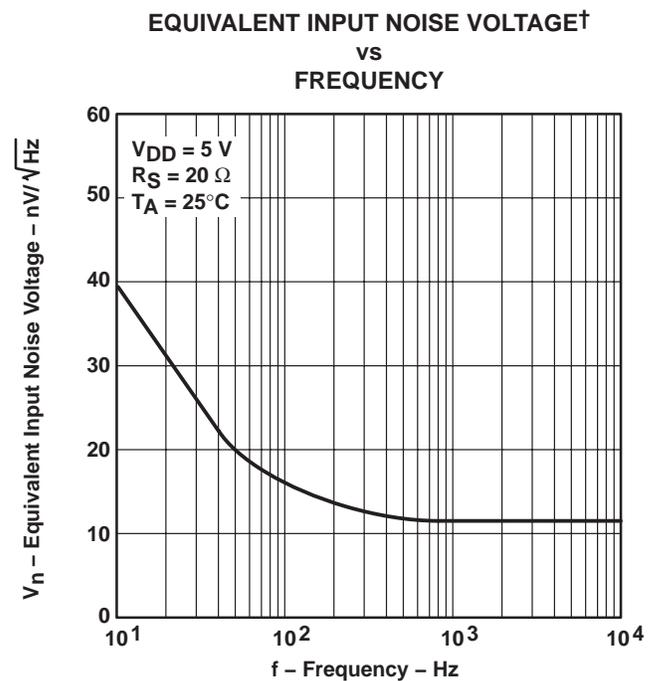
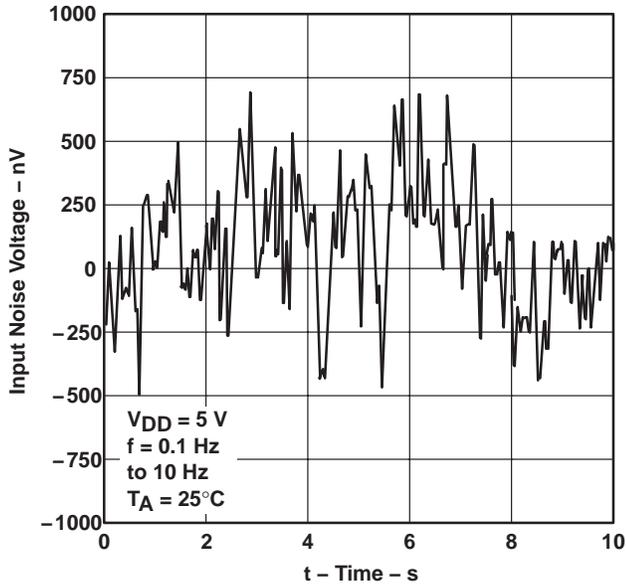


Figure 51

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

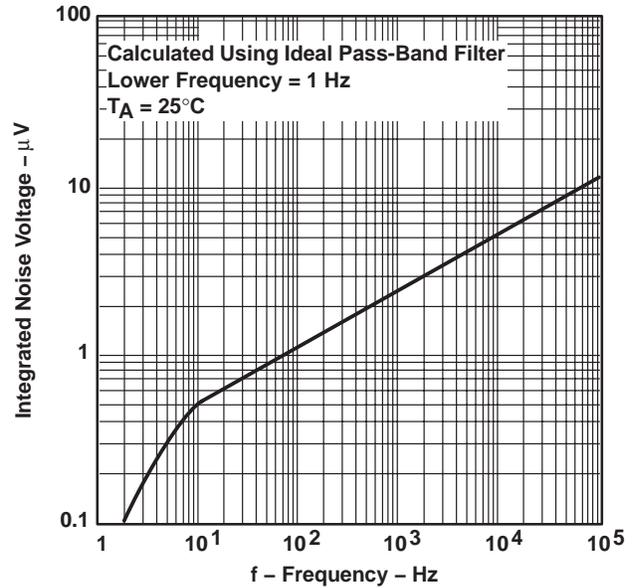
**TYPICAL CHARACTERISTICS**

**INPUT NOISE VOLTAGE OVER  
A 10-SECOND PERIOD†**



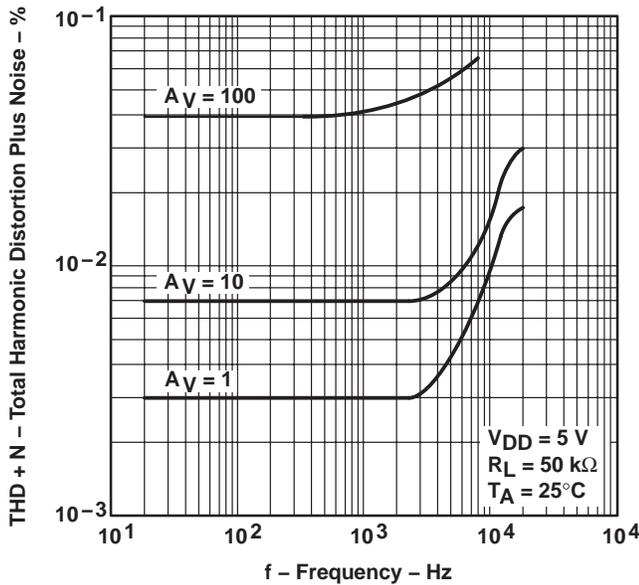
**Figure 52**

**INTEGRATED NOISE VOLTAGE  
VS  
FREQUENCY**



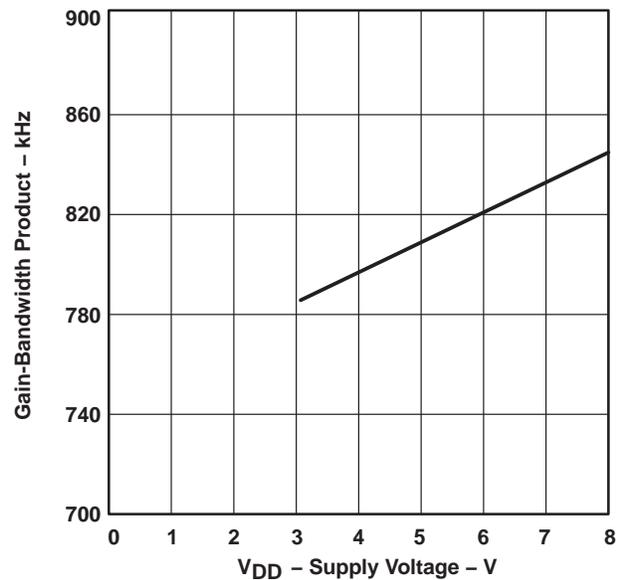
**Figure 53**

**TOTAL HARMONIC DISTORTION PLUS NOISE†  
VS  
FREQUENCY**



**Figure 54**

**GAIN-BANDWIDTH PRODUCT  
VS  
SUPPLY VOLTAGE**



**Figure 55**

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

TYPICAL CHARACTERISTICS

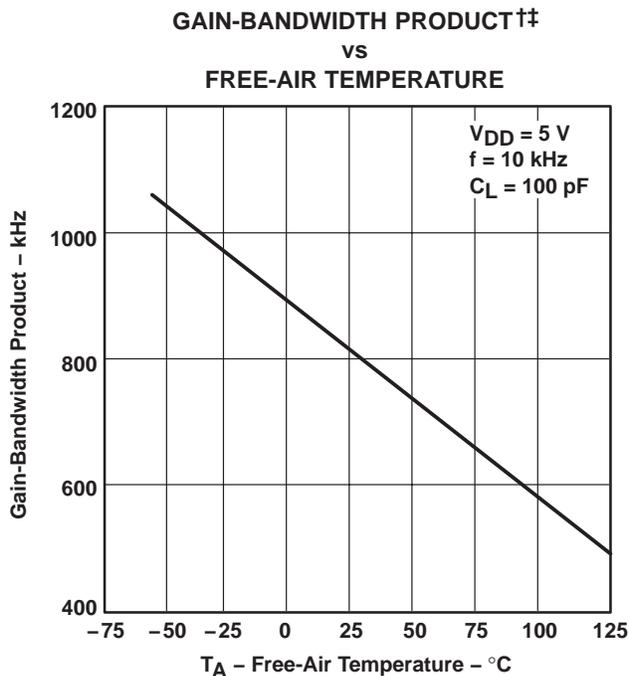


Figure 56

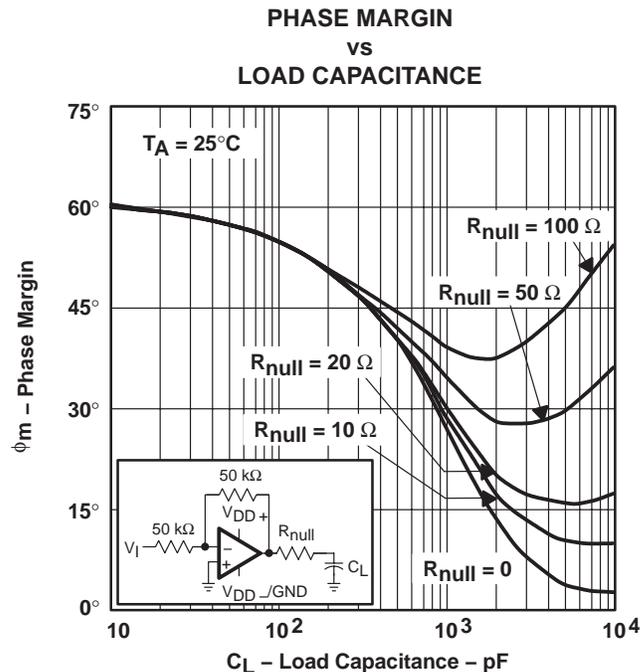


Figure 57

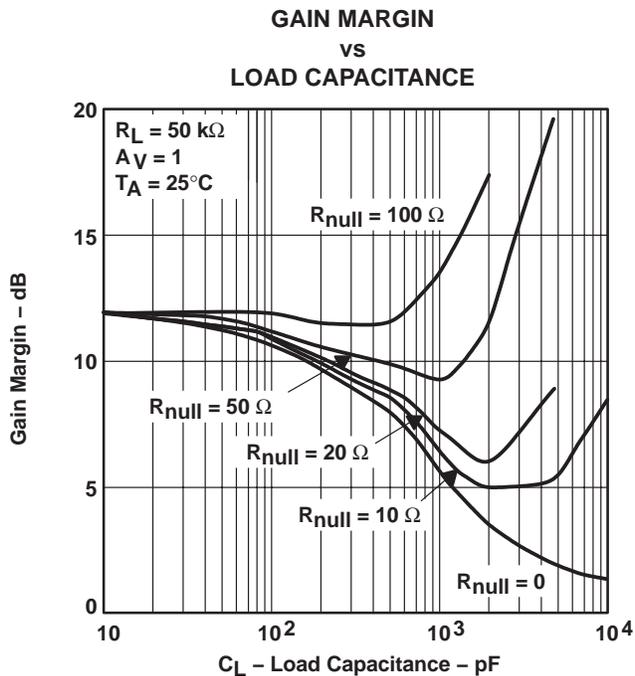


Figure 58

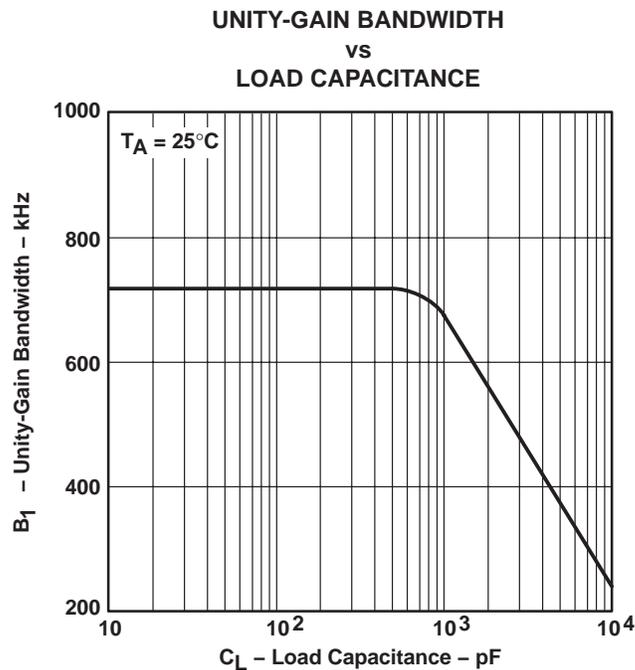
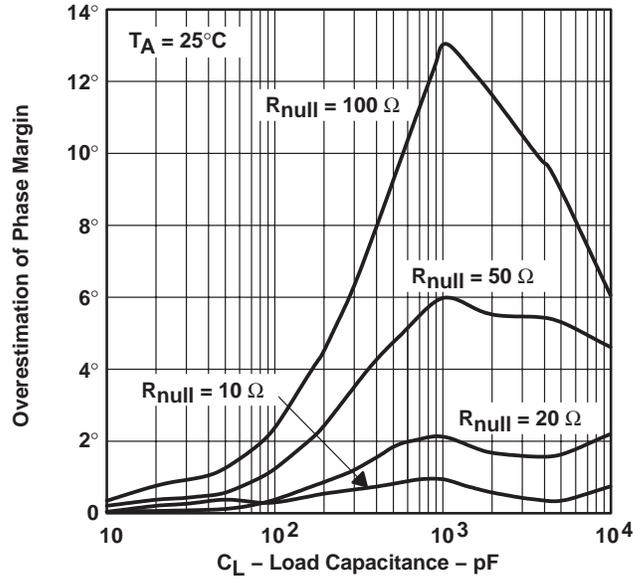


Figure 59

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.  
†† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

OVERESTIMATION OF PHASE MARGIN†  
vs  
LOAD CAPACITANCE



† See application information

Figure 60

## APPLICATION INFORMATION

### driving large capacitive loads

The TLV226x is designed to drive larger capacitive loads than most CMOS operational amplifiers. Figure 51 and Figure 52 illustrate its ability to drive loads greater than 400 pF while maintaining good gain and phase margins ( $R_{null} = 0$ ).

A smaller series resistor ( $R_{null}$ ) at the output of the device (see Figure 61) improves the gain and phase margins when driving large capacitive loads. Figure 51 and Figure 52 show the effects of adding series resistances of 10  $\Omega$ , 20  $\Omega$ , 50  $\Omega$ , and 100  $\Omega$ . The addition of this series resistor has two effects: the first is that it adds a zero to the transfer function and the second is that it reduces the frequency of the pole associated with the output load in the transfer function.

The zero introduced to the transfer function is equal to the series resistance times the load capacitance. To calculate the improvement in phase margin, equation (1) can be used.

$$\Delta\theta_{m1} = \tan^{-1} \left( 2 \times \pi \times \text{UGBW} \times R_{null} \times C_L \right) \quad (1)$$

Where :

$\Delta\theta_{m1}$  = improvement in phase margin

UGBW = unity-gain bandwidth frequency

$R_{null}$  = output series resistance

$C_L$  = load capacitance

The unity-gain bandwidth (UGBW) frequency decreases as the capacitive load increases (see Figure 53). To use equation 1, UGBW must be approximated from Figure 53.

Using equation 1 alone overestimates the improvement in phase margin as illustrated in Figure 59. The overestimation is caused by the decrease in the frequency of the pole associated with the load, providing additional phase shift and reducing the overall improvement in phase margin. The pole associated with the load is reduced by the factor calculated in equation 2.

$$F = \frac{1}{1 + g_m \times R_{null}} \quad (2)$$

Where :

F = factor reducing frequency of pole

$g_m$  = small-signal output transconductance (typically  $4.83 \times 10^{-3}$  mhos)

$R_{null}$  = output series resistance

For the TLV226x, the pole associated with the load is typically 7 MHz with 100-pF load capacitance. This value varies inversely with  $C_L$ : at  $C_L = 10$  pF, use 70 MHz, at  $C_L = 1000$  pF, use 700 kHz, and so on.

Reducing the pole associated with the load introduces phase shift, thereby reducing phase margin. This results in an error in the increase in phase margin expected by considering the zero alone (equation 1). Equation 3 approximates the reduction in phase margin due to the movement of the pole associated with the load. The result of this equation can be subtracted from the result of the equation 1 to better approximate the improvement in phase margin.

**APPLICATION INFORMATION**

**driving large capacitive loads (continued)**

$$\Delta\theta_{m2} = \tan^{-1} \left[ \frac{UGBW}{(F \times P_2)} \right] - \tan^{-1} \left( \frac{UGBW}{P_2} \right) \tag{3}$$

Where :

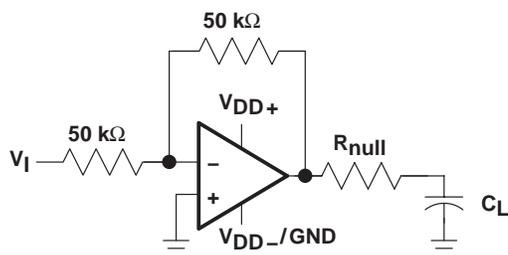
$\Delta\theta_{m2}$  = reduction in phase margin

UGBW = unity-gain bandwidth frequency

F = factor from equation (2)

$P_2$  = unadjusted pole (70 MHz @ 10 pF, 7 MHz @ 100 pF, etc.)

Using these equations with Figure 60 and Figure 61 enables the designer to choose the appropriate output series resistance to optimize the design of circuits driving large capacitive loads.



**Figure 61. Series-Resistance Circuit**

APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*™, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 5) and subcircuit in Figure 62 are generated using the TLV226x typical electrical and operating characteristics at  $T_A = 25^\circ\text{C}$ . Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 5: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Intergrated Circuit Operational Amplifiers," *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

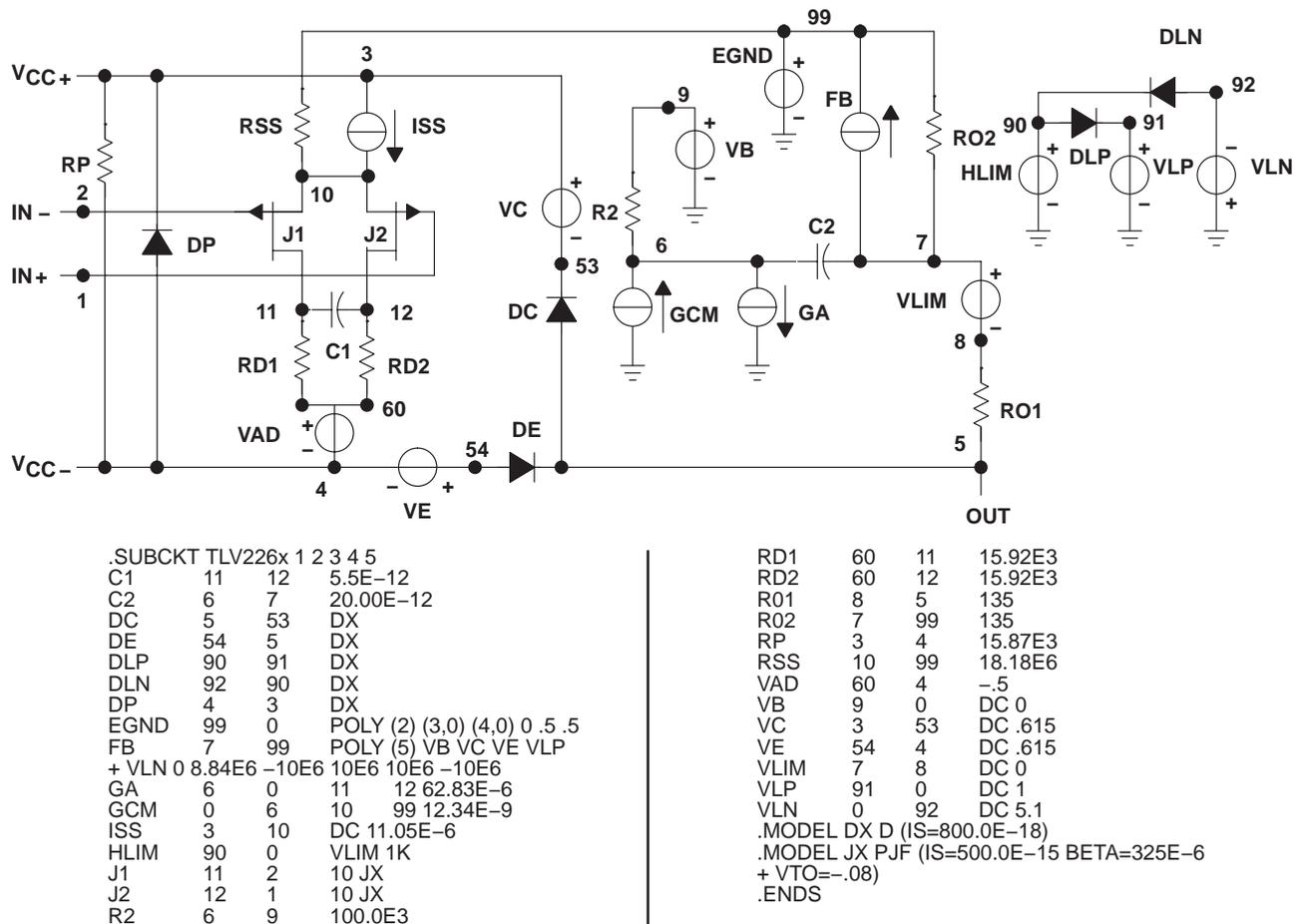


Figure 62. Boyle Macromodel and Subcircuit

*PSpice* and *Parts* are trademarks of MicroSim Corporation.

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">5962-9550401QPA</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9550401QPA TLV2262M
<a href="#">5962-9550403QHA</a>	Active	Production	CFP (U)   10	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9550403QHA TLV2262AM
<a href="#">5962-9550403QPA</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9550403QPA TLV2262AM
<a href="#">5962-9550404QCA</a>	Active	Production	CDIP (J)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9550404QC A TLV2264AMJB
<a href="#">5962-9550404QDA</a>	Active	Production	CFP (W)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9550404QD A TLV2264AMWB
<a href="#">TLV2262AID</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2262A
TLV2262AID.A	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2262A
<a href="#">TLV2262AIDR</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2262A
TLV2262AIDR.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2262A
<a href="#">TLV2262AIP</a>	Active	Production	PDIP (P)   8	50   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2262AI
TLV2262AIP.A	Active	Production	PDIP (P)   8	50   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2262AI
<a href="#">TLV2262AIPW</a>	Obsolete	Production	TSSOP (PW)   8	-	-	Call TI	Call TI	-40 to 125	TY262A
<a href="#">TLV2262AIPWR</a>	Active	Production	TSSOP (PW)   8	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY262A
TLV2262AIPWR.A	Active	Production	TSSOP (PW)   8	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY262A
<a href="#">TLV2262AMJGB</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9550403QPA TLV2262AM
TLV2262AMJGB.A	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9550403QPA TLV2262AM
<a href="#">TLV2262AMUB</a>	Active	Production	CFP (U)   10	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9550403QHA TLV2262AM
TLV2262AMUB.A	Active	Production	CFP (U)   10	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9550403QHA TLV2262AM
<a href="#">TLV2262ID</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2262I
TLV2262ID.A	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2262I
<a href="#">TLV2262IDR</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2262I

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2262IDR.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2262I
TLV2262IDRG4	Active	Production	SOIC (D)   8	2500   LARGE T&R	-	Call TI	Call TI	-40 to 125	
<a href="#">TLV2262IP</a>	Active	Production	PDIP (P)   8	50   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2262IP
TLV2262IP.A	Active	Production	PDIP (P)   8	50   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2262IP
<a href="#">TLV2262IPW</a>	Obsolete	Production	TSSOP (PW)   8	-	-	Call TI	Call TI	-40 to 125	TY2262
<a href="#">TLV2262IPWR</a>	Active	Production	TSSOP (PW)   8	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2262
TLV2262IPWR.A	Active	Production	TSSOP (PW)   8	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2262
<a href="#">TLV2262MJGB</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9550401QPA TLV2262M
TLV2262MJGB.A	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9550401QPA TLV2262M
<a href="#">TLV2264AID</a>	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2264AI
TLV2264AID.B	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2264AI
<a href="#">TLV2264AIDR</a>	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2264AI
TLV2264AIDR.B	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2264AI
TLV2264AIDRG4	Active	Production	SOIC (D)   14	2500   LARGE T&R	-	Call TI	Call TI	-40 to 125	
<a href="#">TLV2264AIN</a>	Active	Production	PDIP (N)   14	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2264AIN
TLV2264AIN.A	Active	Production	PDIP (N)   14	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2264AIN
<a href="#">TLV2264AIPW</a>	Obsolete	Production	TSSOP (PW)   14	-	-	Call TI	Call TI	-40 to 125	P2264AI
<a href="#">TLV2264AIPWR</a>	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	P2264AI
TLV2264AIPWR.B	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	P2264AI
<a href="#">TLV2264AMJB</a>	Active	Production	CDIP (J)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9550404QC A TLV2264AMJB
TLV2264AMJB.A	Active	Production	CDIP (J)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9550404QC A TLV2264AMJB
<a href="#">TLV2264AMWB</a>	Active	Production	CFP (W)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9550404QD A TLV2264AMWB
TLV2264AMWB.A	Active	Production	CFP (W)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9550404QD A TLV2264AMWB

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">TLV2264AQD</a>	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2264A
TLV2264AQD.A	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2264A
TLV2264AQD.B	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2264A
<a href="#">TLV2264ID</a>	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2264I
TLV2264ID.B	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2264I
<a href="#">TLV2264IDR</a>	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2264I
TLV2264IDR.B	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2264I
<a href="#">TLV2264IN</a>	Active	Production	PDIP (N)   14	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2264IN
TLV2264IN.A	Active	Production	PDIP (N)   14	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2264IN
<a href="#">TLV2264IPWR</a>	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	P2264I
TLV2264IPWR.B	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	P2264I
<a href="#">TLV2264QD</a>	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2264
TLV2264QD.A	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2264
TLV2264QD.B	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2264

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

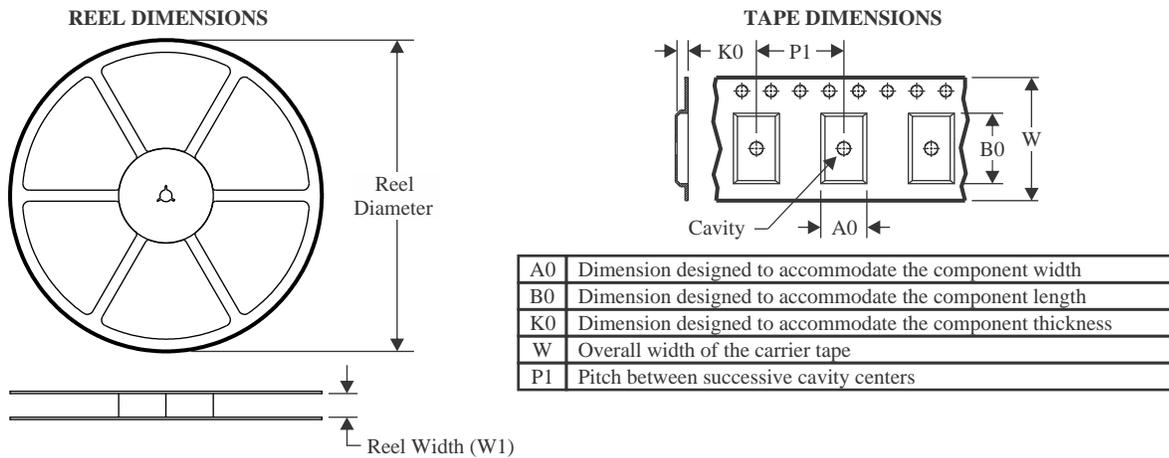
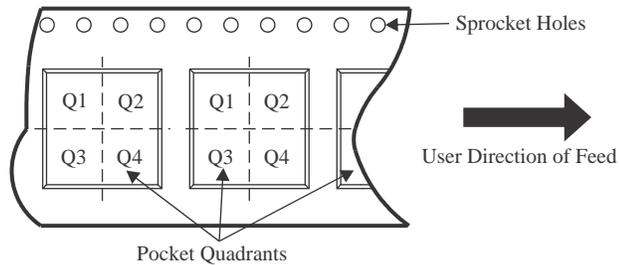
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF TLV2262, TLV2262A, TLV2262AM, TLV2262M, TLV2264A, TLV2264AM :**

- Catalog : [TLV2262A](#), [TLV2262](#), [TLV2264A](#)
- Automotive : [TLV2262A-Q1](#), [TLV2262A-Q1](#), [TLV2264A-Q1](#), [TLV2264A-Q1](#)
- Military : [TLV2262M](#), [TLV2262AM](#), [TLV2264AM](#)

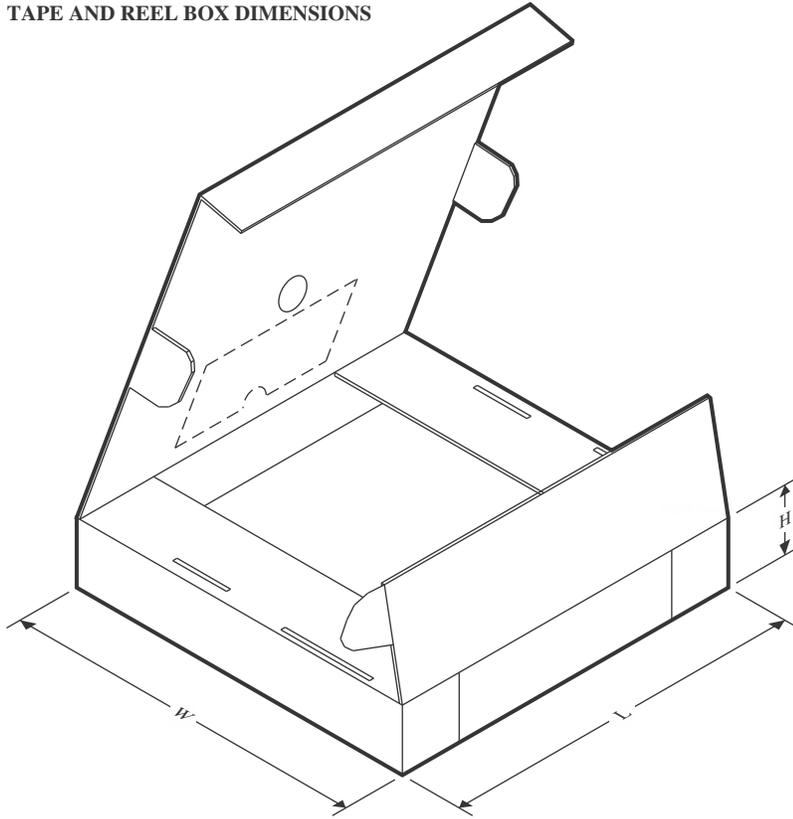
NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military - QML certified for Military and Defense Applications

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


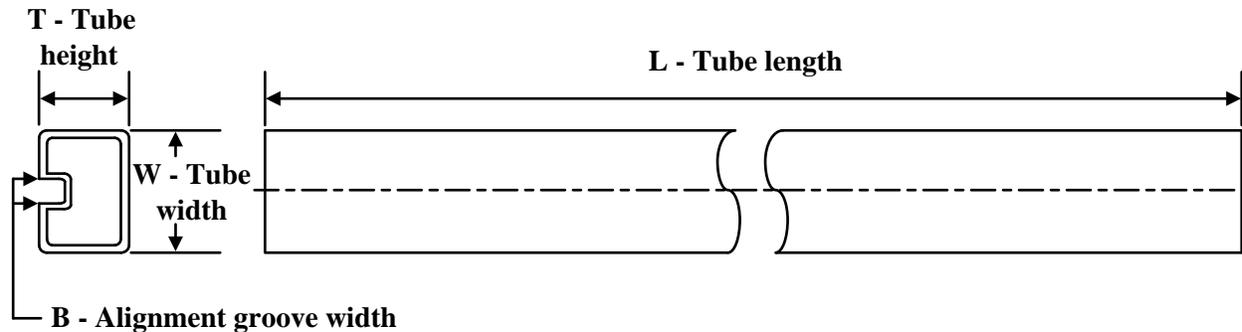
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2262AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2262AIPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TLV2262IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2262IPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TLV2264AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2264AIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2264IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2264IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2262AIDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2262AIPWR	TSSOP	PW	8	2000	353.0	353.0	32.0
TLV2262IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2262IPWR	TSSOP	PW	8	2000	353.0	353.0	32.0
TLV2264AIDR	SOIC	D	14	2500	340.5	336.1	32.0
TLV2264AIPWR	TSSOP	PW	14	2000	353.0	353.0	32.0
TLV2264IDR	SOIC	D	14	2500	353.0	353.0	32.0
TLV2264IPWR	TSSOP	PW	14	2000	353.0	353.0	32.0

**TUBE**


\*All dimensions are nominal

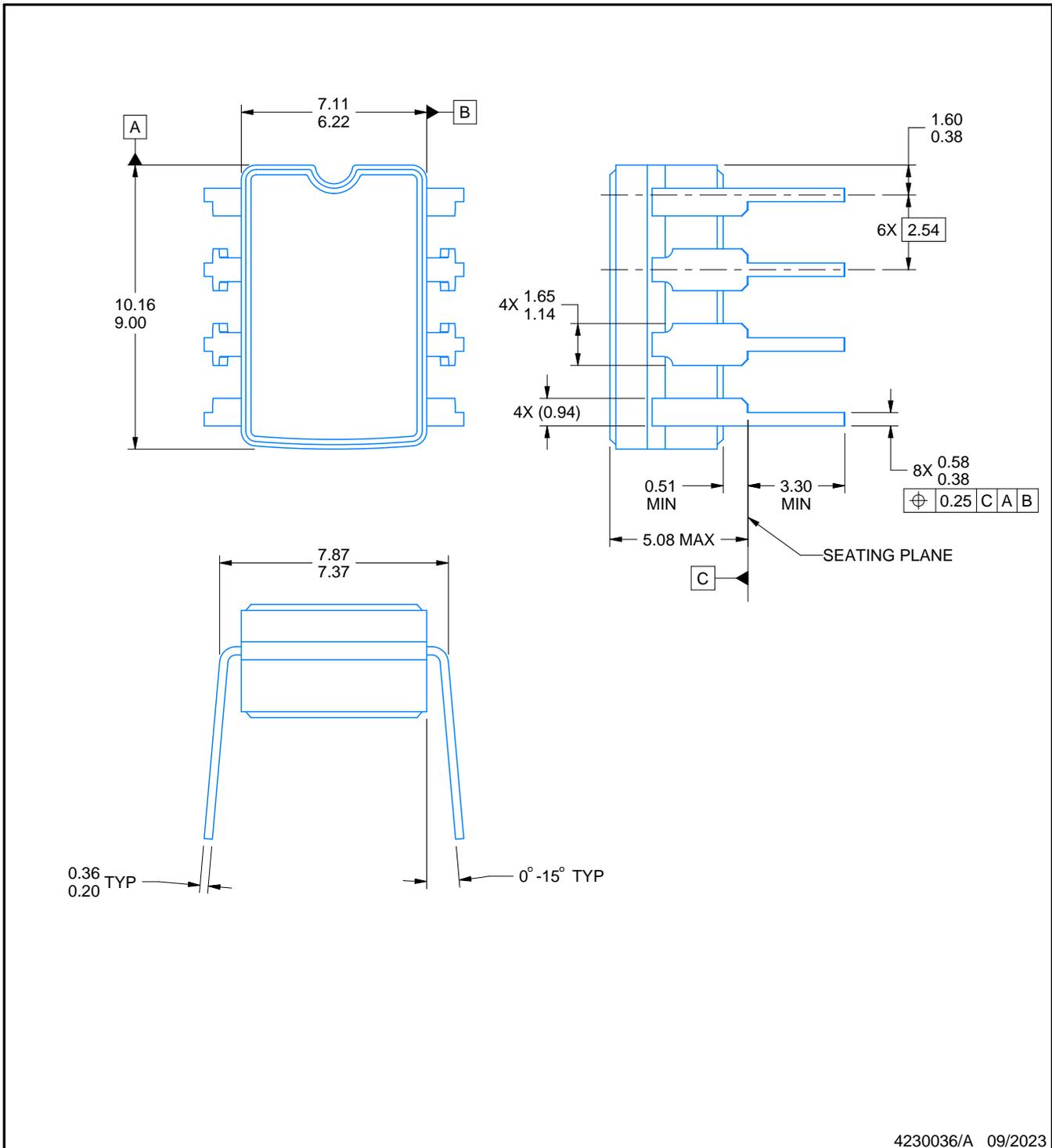
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
5962-9550403QHA	U	CFP	10	25	506.98	26.16	6220	NA
5962-9550404QDA	W	CFP	14	25	506.98	26.16	6220	NA
TLV2262AID	D	SOIC	8	75	507	8	3940	4.32
TLV2262AID.A	D	SOIC	8	75	507	8	3940	4.32
TLV2262AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2262AIP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2262AMUB	U	CFP	10	25	506.98	26.16	6220	NA
TLV2262AMUB.A	U	CFP	10	25	506.98	26.16	6220	NA
TLV2262ID	D	SOIC	8	75	507	8	3940	4.32
TLV2262ID.A	D	SOIC	8	75	507	8	3940	4.32
TLV2262IP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2262IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2264AID	D	SOIC	14	50	507	8	3940	4.32
TLV2264AID.B	D	SOIC	14	50	507	8	3940	4.32
TLV2264AIN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2264AIN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLV2264AMWB	W	CFP	14	25	506.98	26.16	6220	NA
TLV2264AMWB.A	W	CFP	14	25	506.98	26.16	6220	NA
TLV2264AQD	D	SOIC	14	50	507	8	3940	4.32
TLV2264AQD.A	D	SOIC	14	50	507	8	3940	4.32
TLV2264AQD.B	D	SOIC	14	50	507	8	3940	4.32
TLV2264ID	D	SOIC	14	50	507	8	3940	4.32
TLV2264ID.B	D	SOIC	14	50	507	8	3940	4.32
TLV2264IN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2264IN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLV2264QD	D	SOIC	14	50	505.46	6.76	3810	4
TLV2264QD.A	D	SOIC	14	50	505.46	6.76	3810	4
TLV2264QD.B	D	SOIC	14	50	505.46	6.76	3810	4

# PACKAGE OUTLINE

JG0008A

CDIP - 5.08 mm max height

CERAMIC DUAL IN-LINE PACKAGE



**NOTES:**

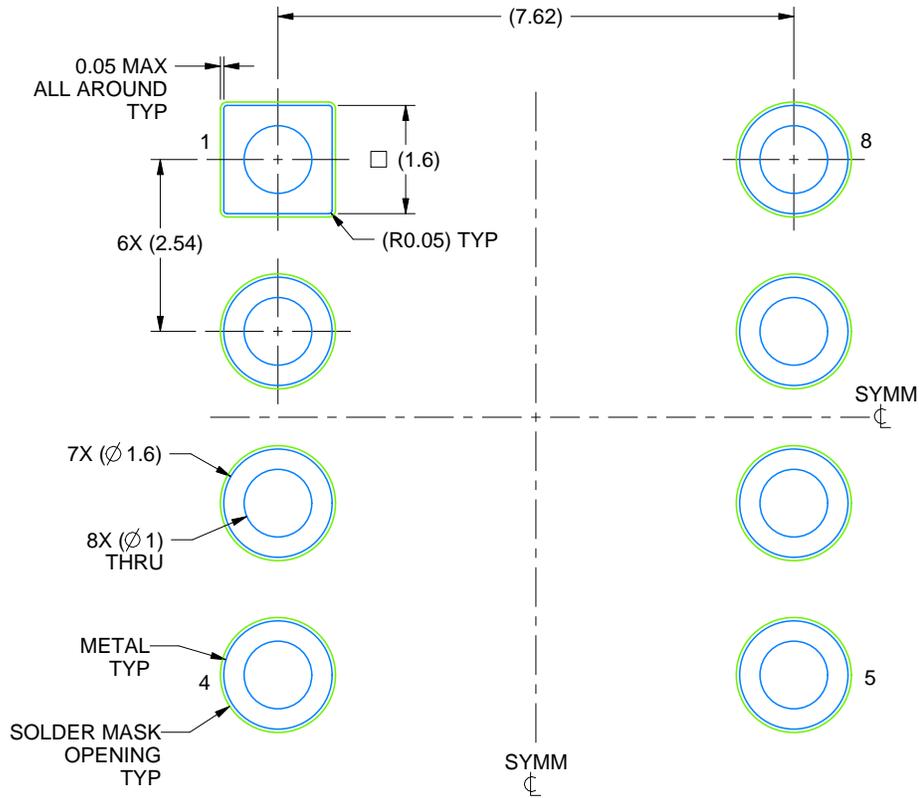
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package can be hermetically sealed with a ceramic lid using glass frit.
4. Index point is provided on cap for terminal identification.
5. Falls within MIL STD 1835 GDIP1-T8

# EXAMPLE BOARD LAYOUT

JG0008A

CDIP - 5.08 mm max height

CERAMIC DUAL IN-LINE PACKAGE



LAND PATTERN EXAMPLE  
NON SOLDER MASK DEFINED  
SCALE: 9X

4230036/A 09/2023



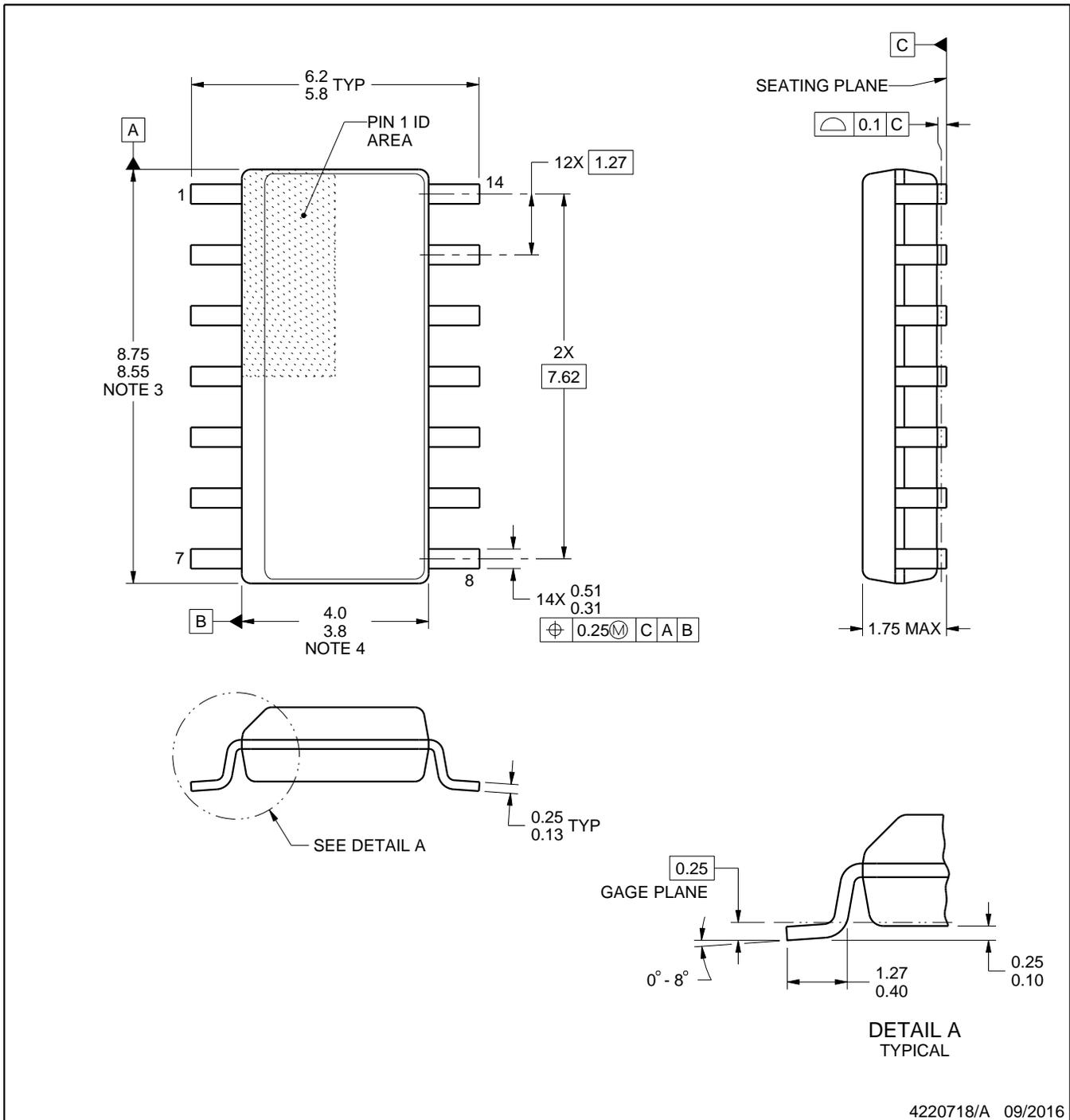
D0014A



# PACKAGE OUTLINE

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4220718/A 09/2016

NOTES:

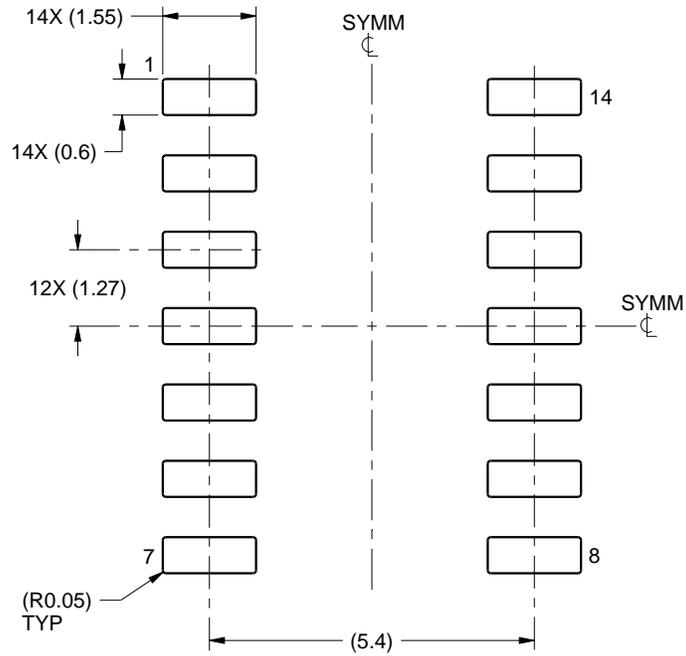
- All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- Reference JEDEC registration MS-012, variation AB.

# EXAMPLE BOARD LAYOUT

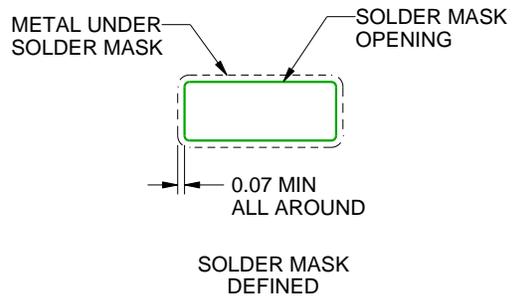
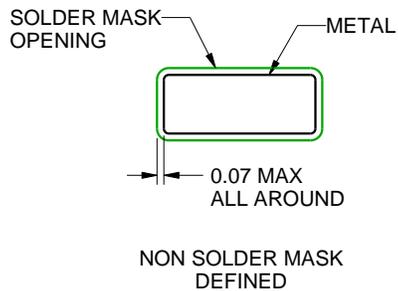
D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
SCALE:8X



SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

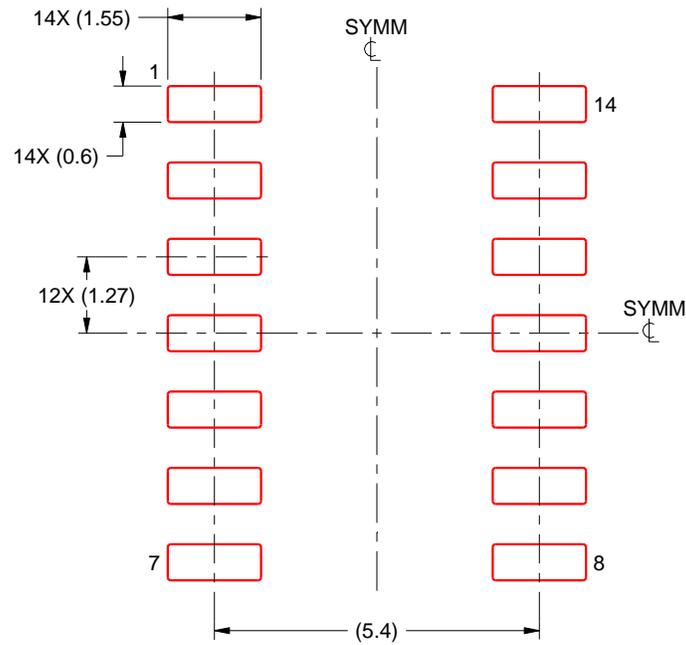
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:8X

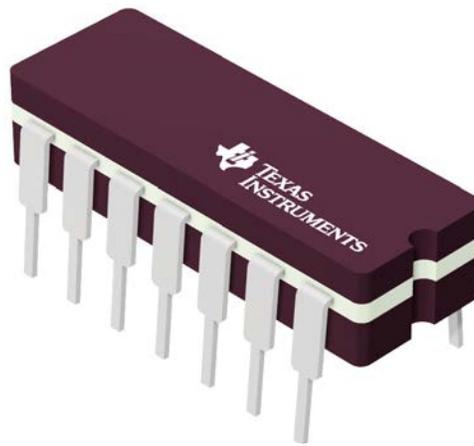
4220718/A 09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

J 14

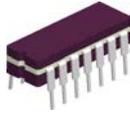
**GENERIC PACKAGE VIEW**  
**CDIP - 5.08 mm max height**  
CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

4040083-5/G

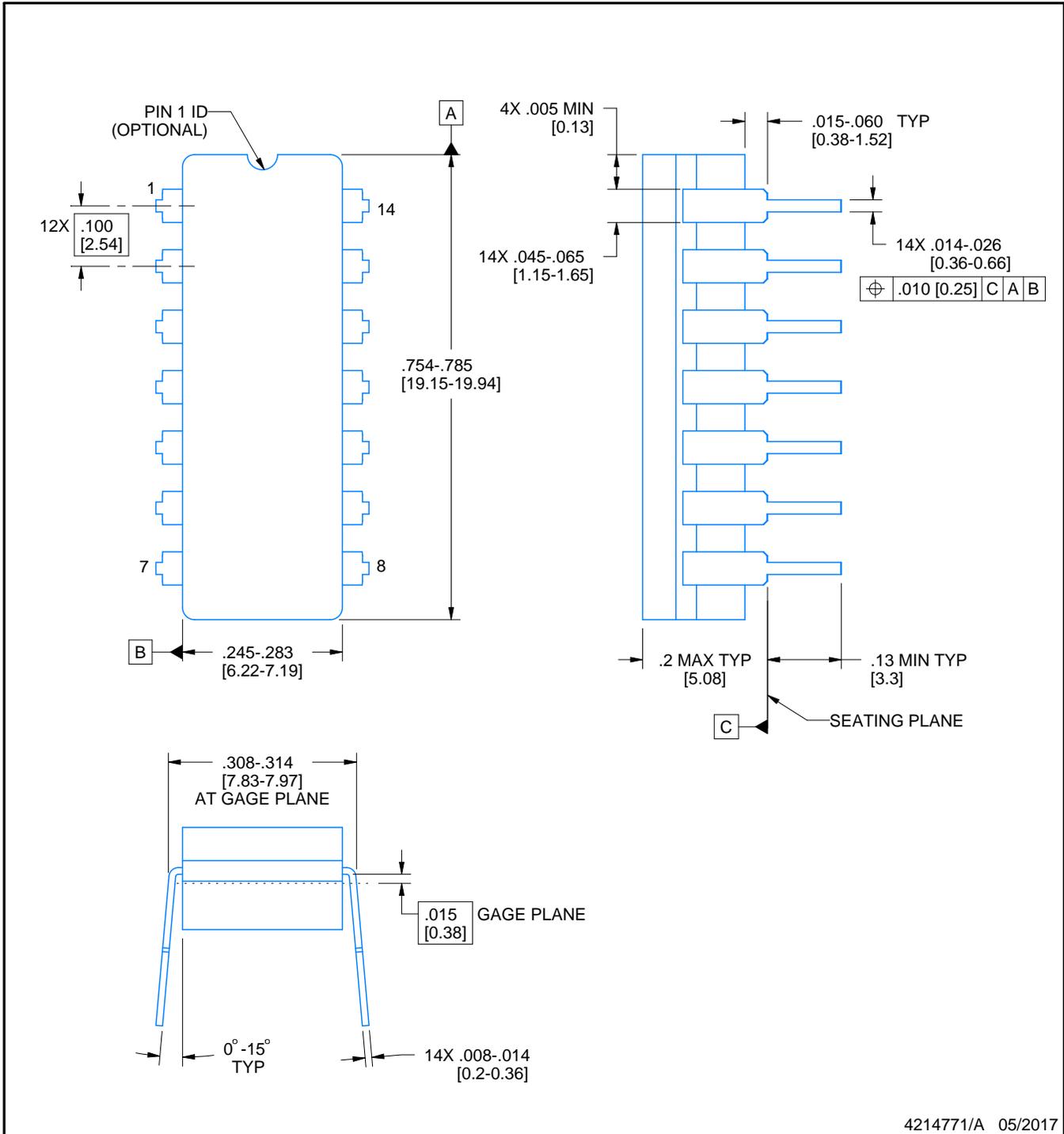
J0014A



# PACKAGE OUTLINE

CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



4214771/A 05/2017

NOTES:

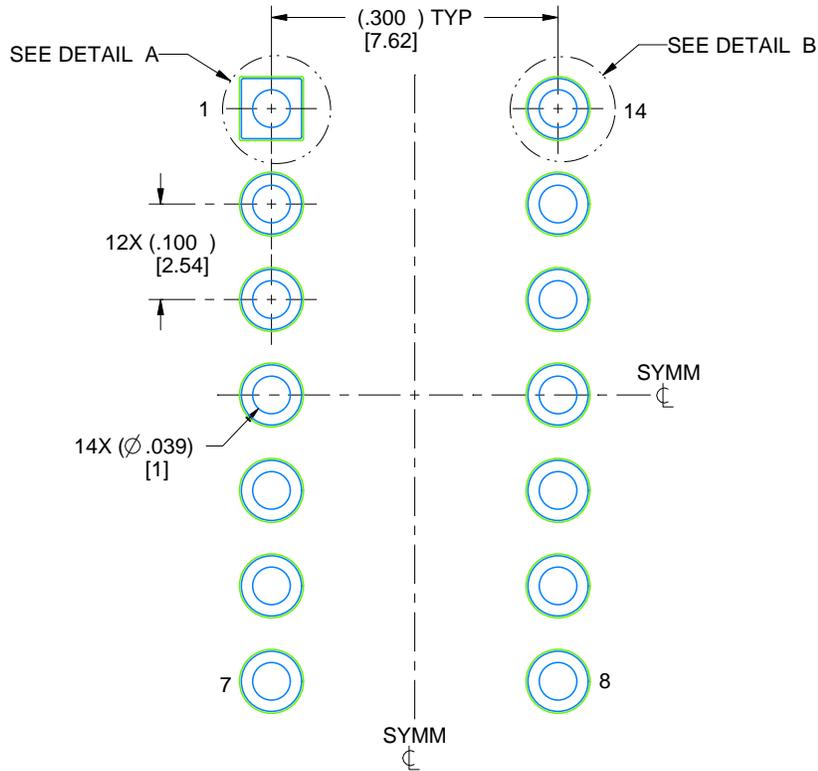
1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package is hermetically sealed with a ceramic lid using glass frit.
4. Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
5. Falls within MIL-STD-1835 and GDIP1-T14.

# EXAMPLE BOARD LAYOUT

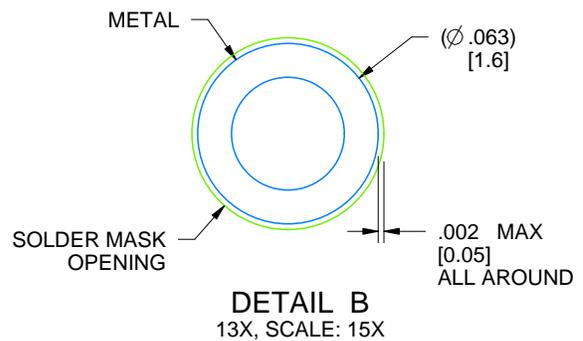
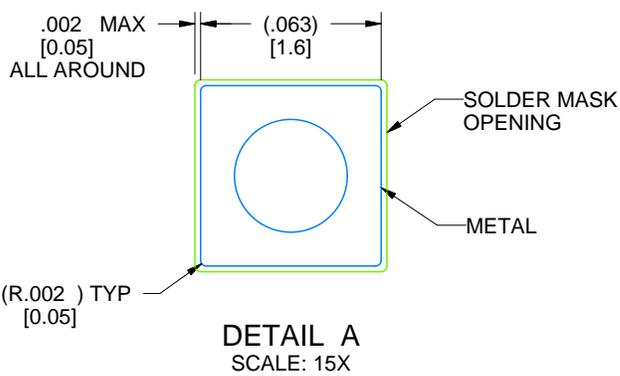
J0014A

CDIP - 5.08 mm max height

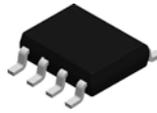
CERAMIC DUAL IN LINE PACKAGE



LAND PATTERN EXAMPLE  
NON-SOLDER MASK DEFINED  
SCALE: 5X



4214771/A 05/2017

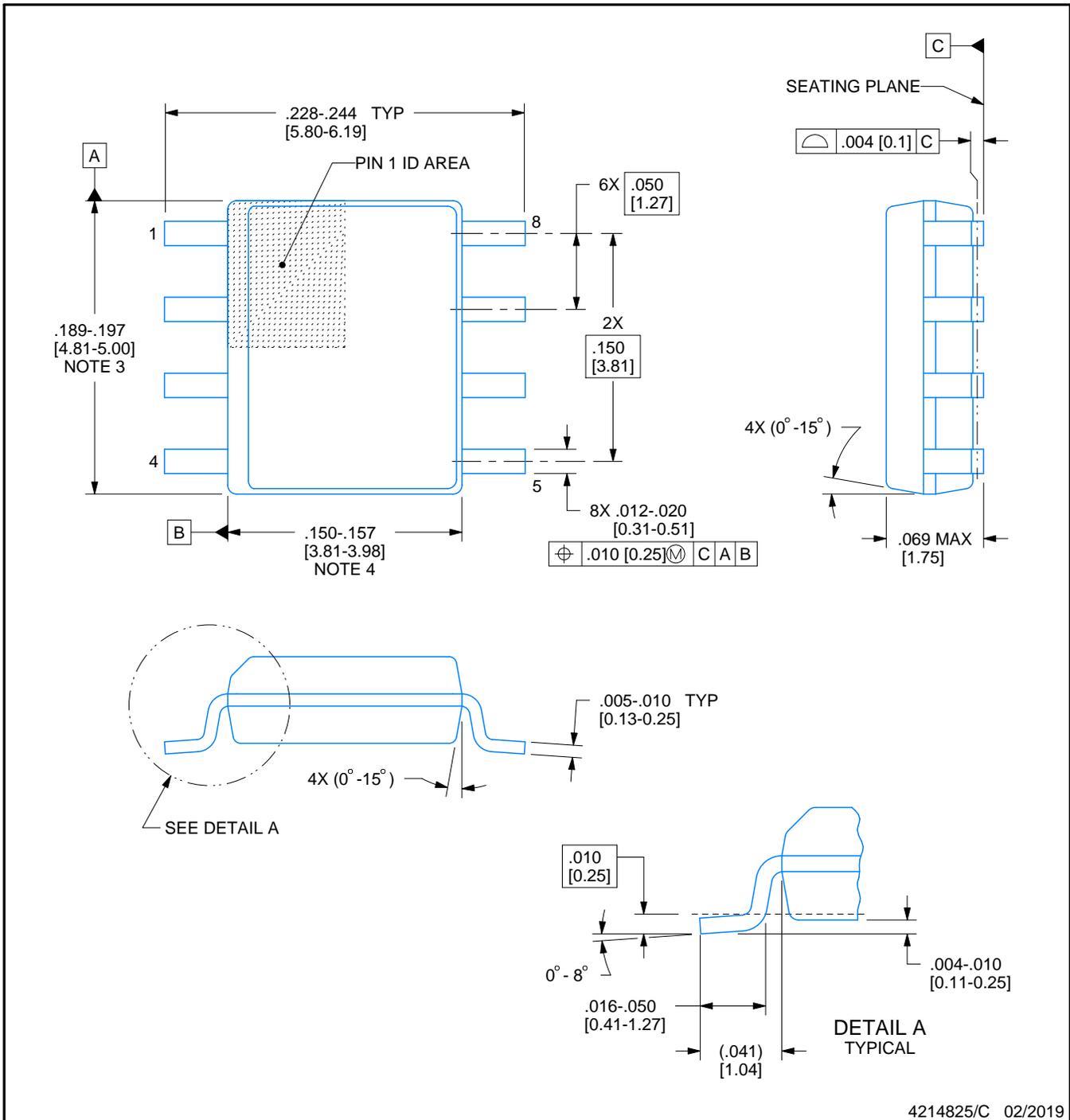


D0008A

# PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

## NOTES:

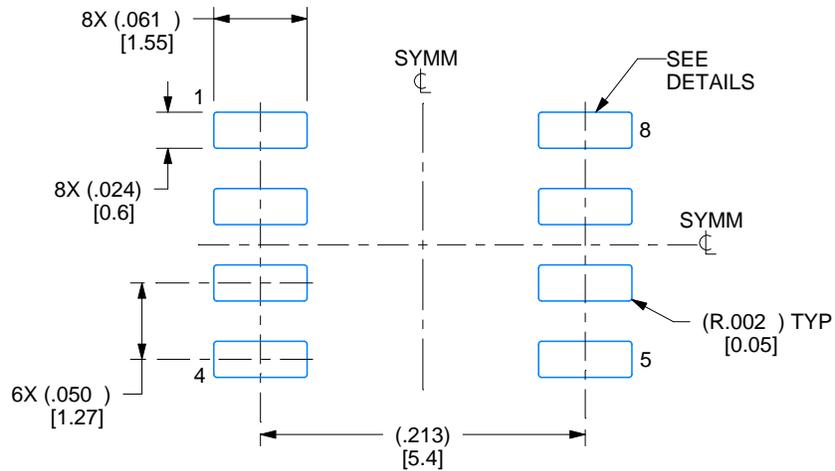
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed  $.006$  [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

# EXAMPLE BOARD LAYOUT

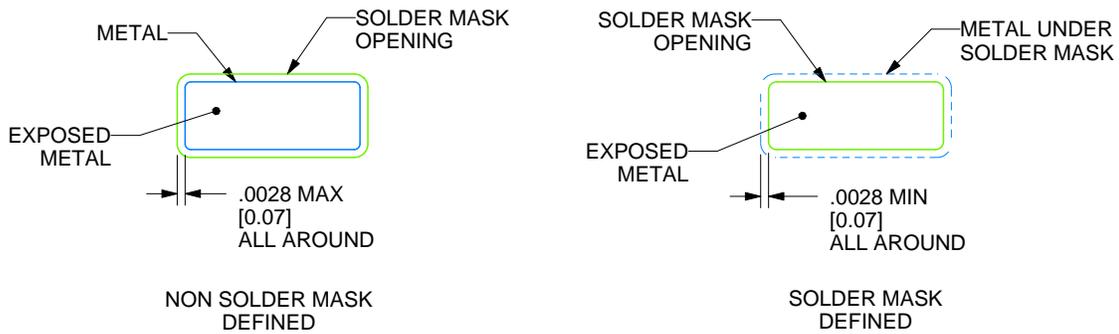
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
 EXPOSED METAL SHOWN  
 SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

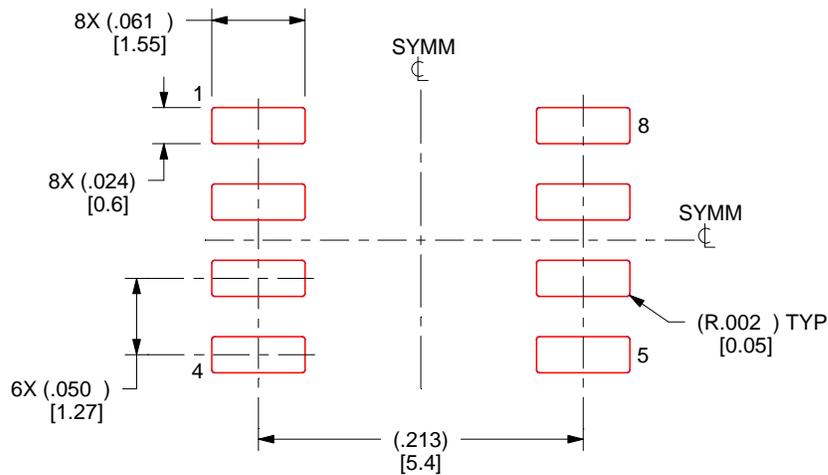
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

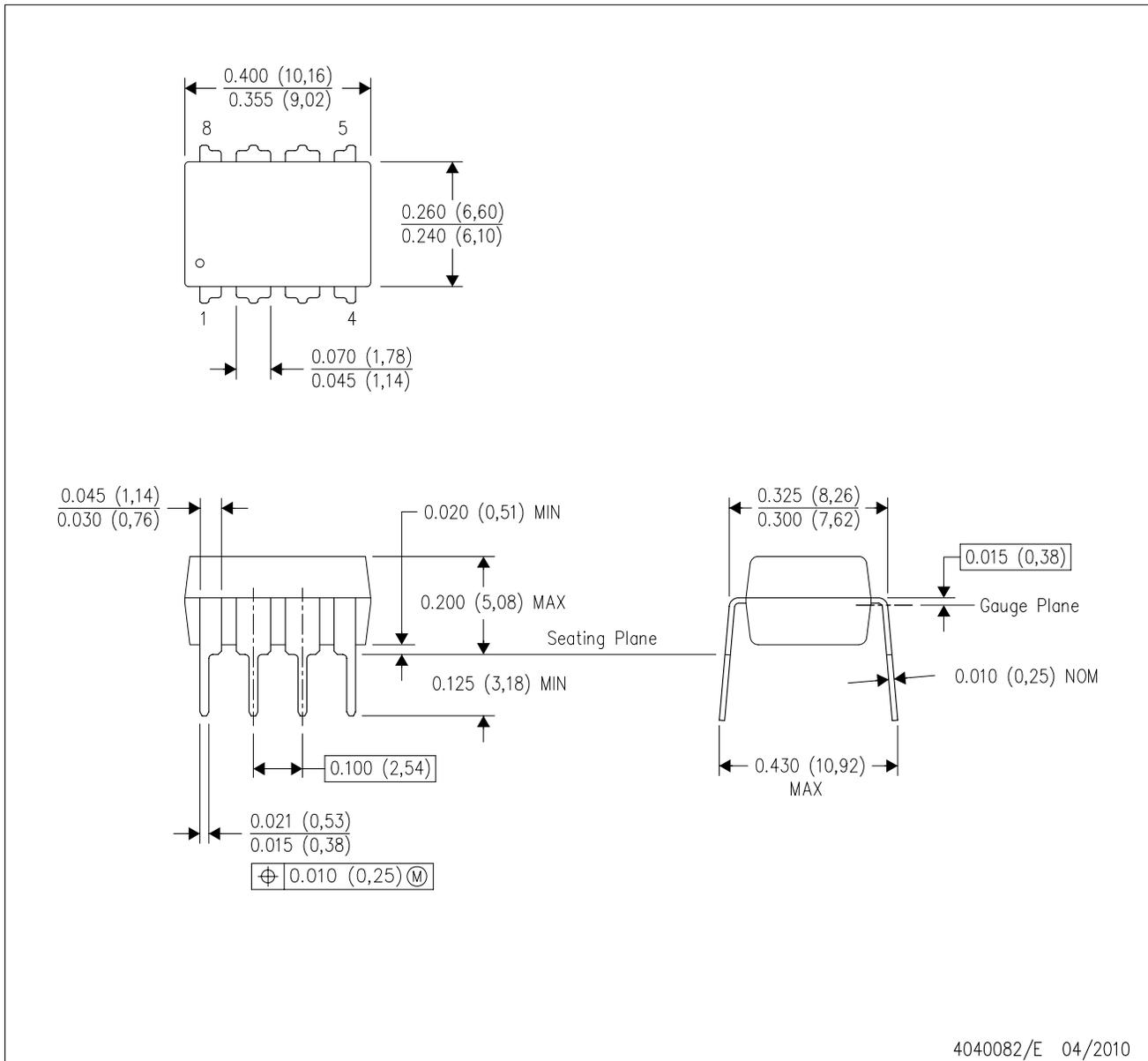
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE

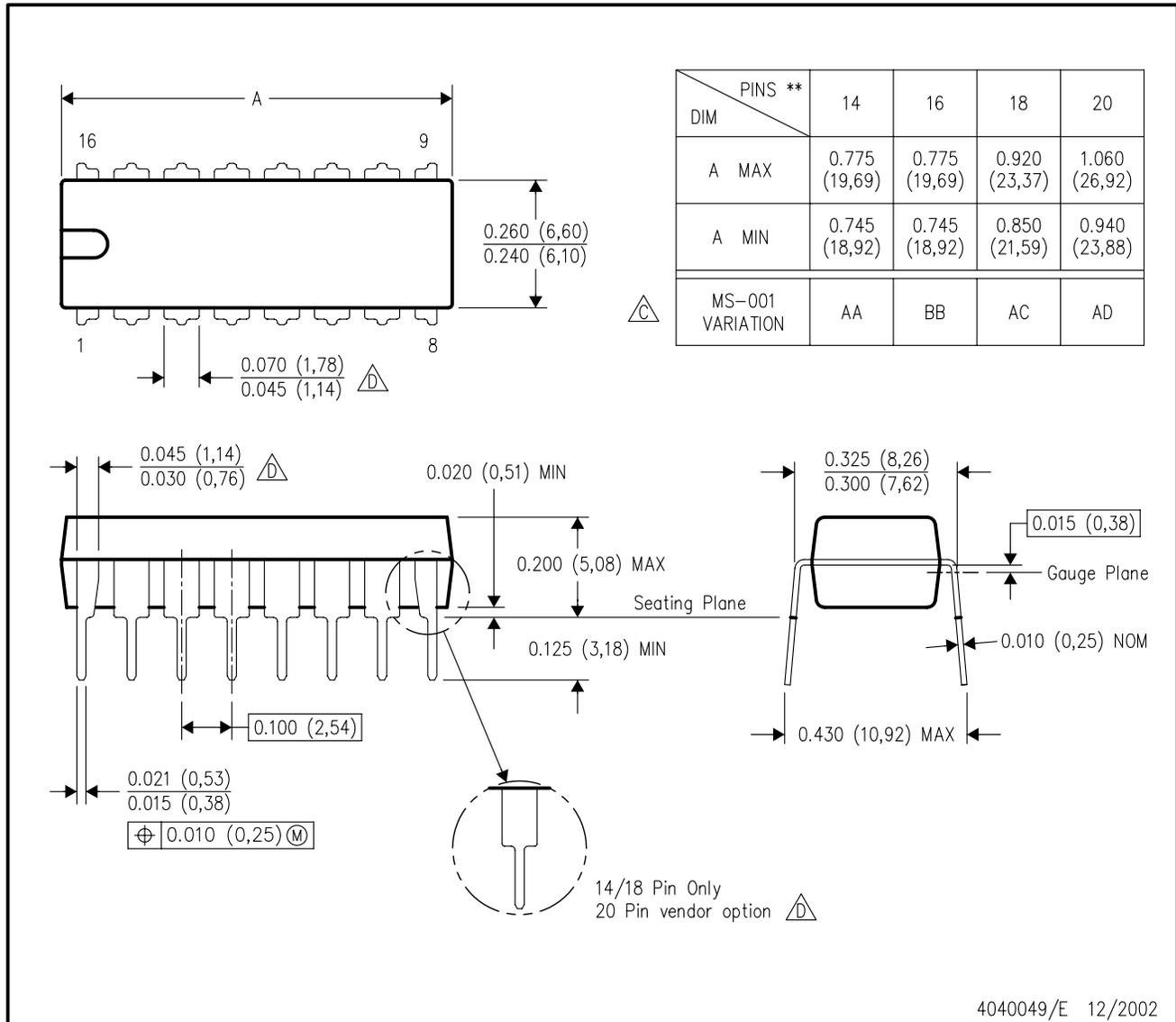


- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Falls within JEDEC MS-001 variation BA.

N (R-PDIP-T\*\*)

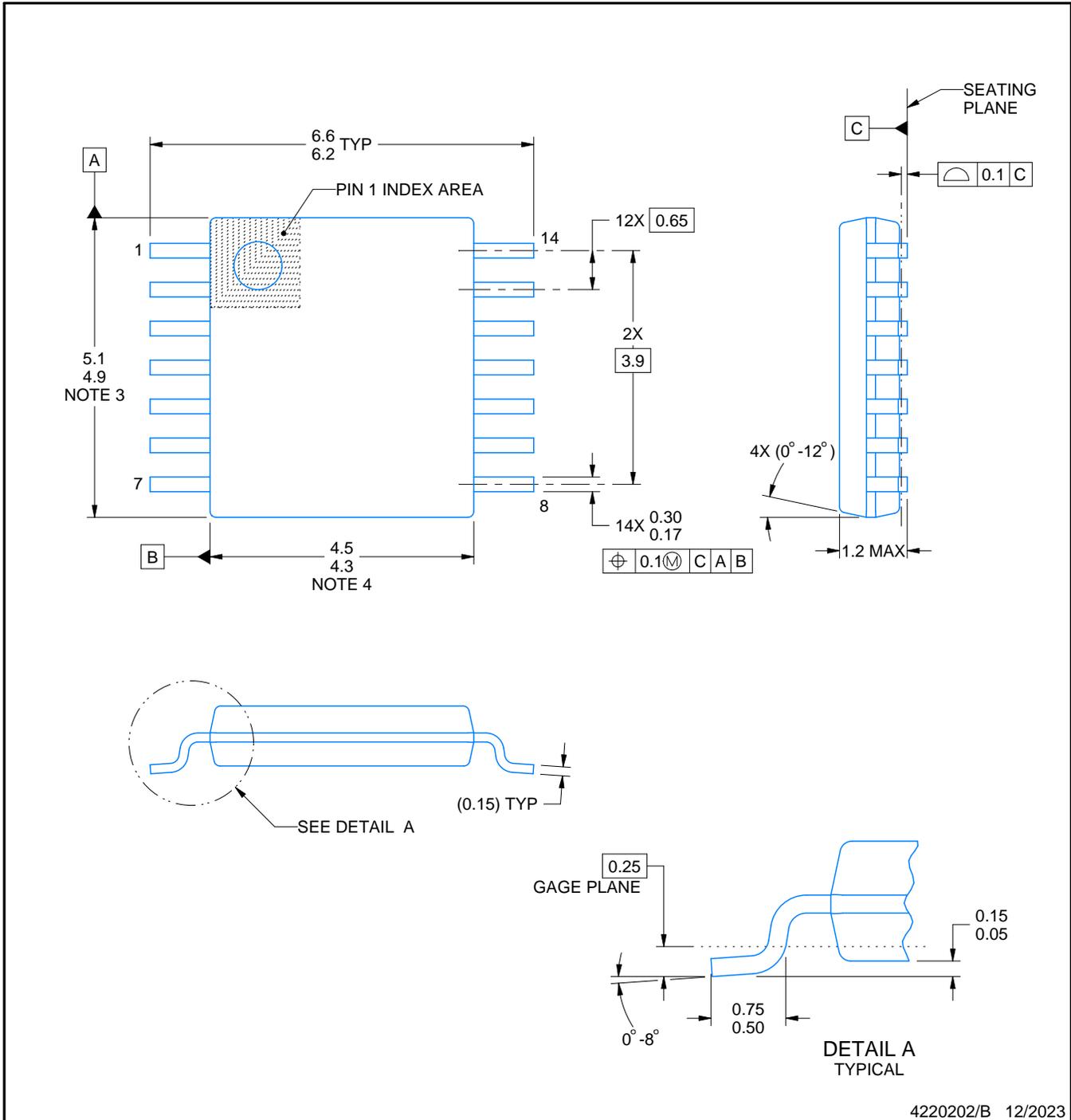
PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - $\triangle C$  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
  - $\triangle D$  The 20 pin end lead shoulder width is a vendor option, either half or full width.

4040049/E 12/2002



4220202/B 12/2023

NOTES:

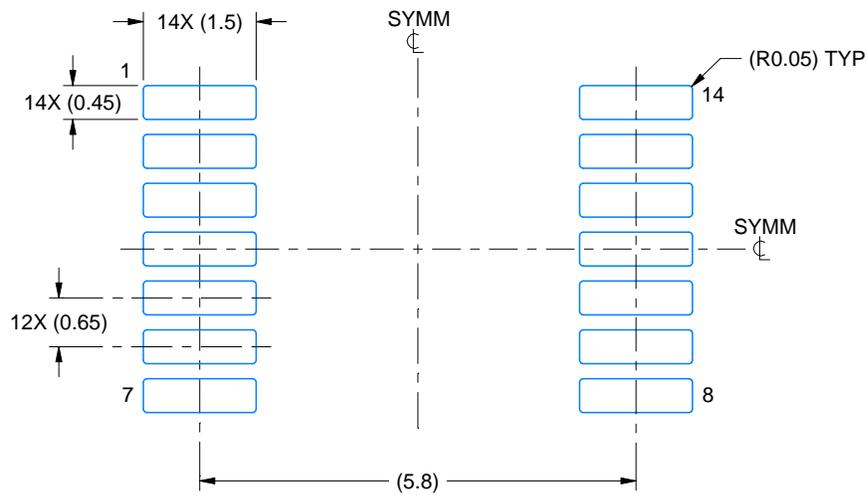
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

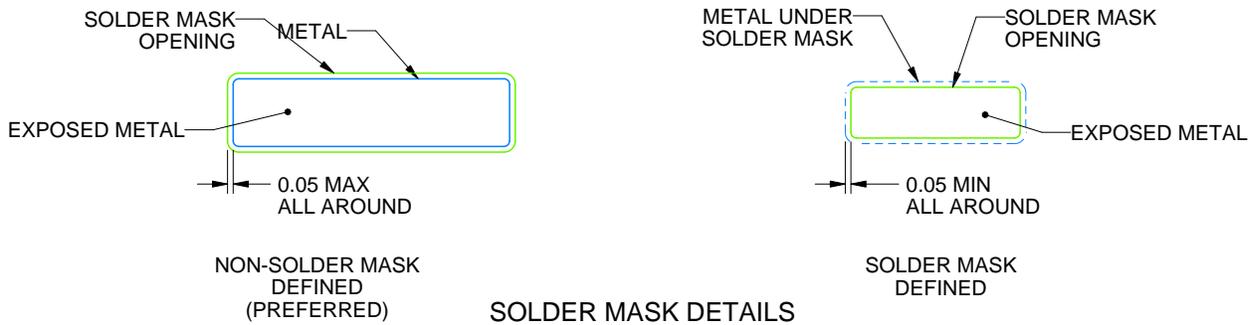
PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



4220202/B 12/2023

NOTES: (continued)

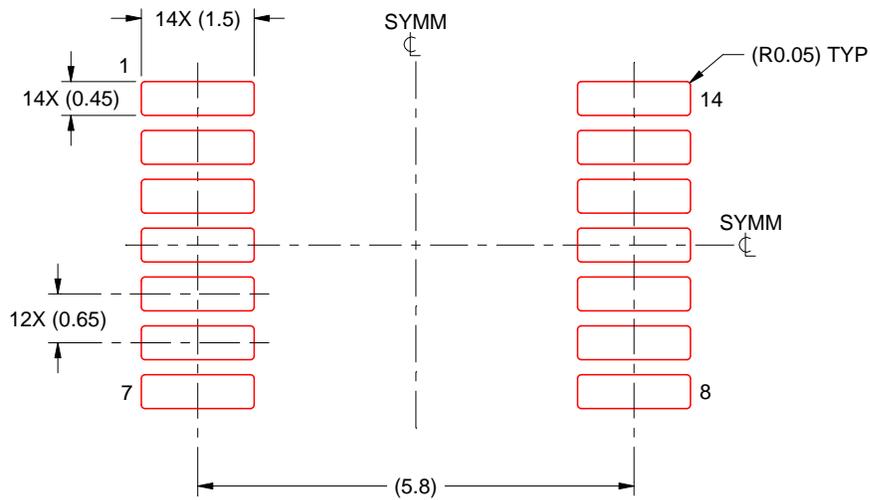
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

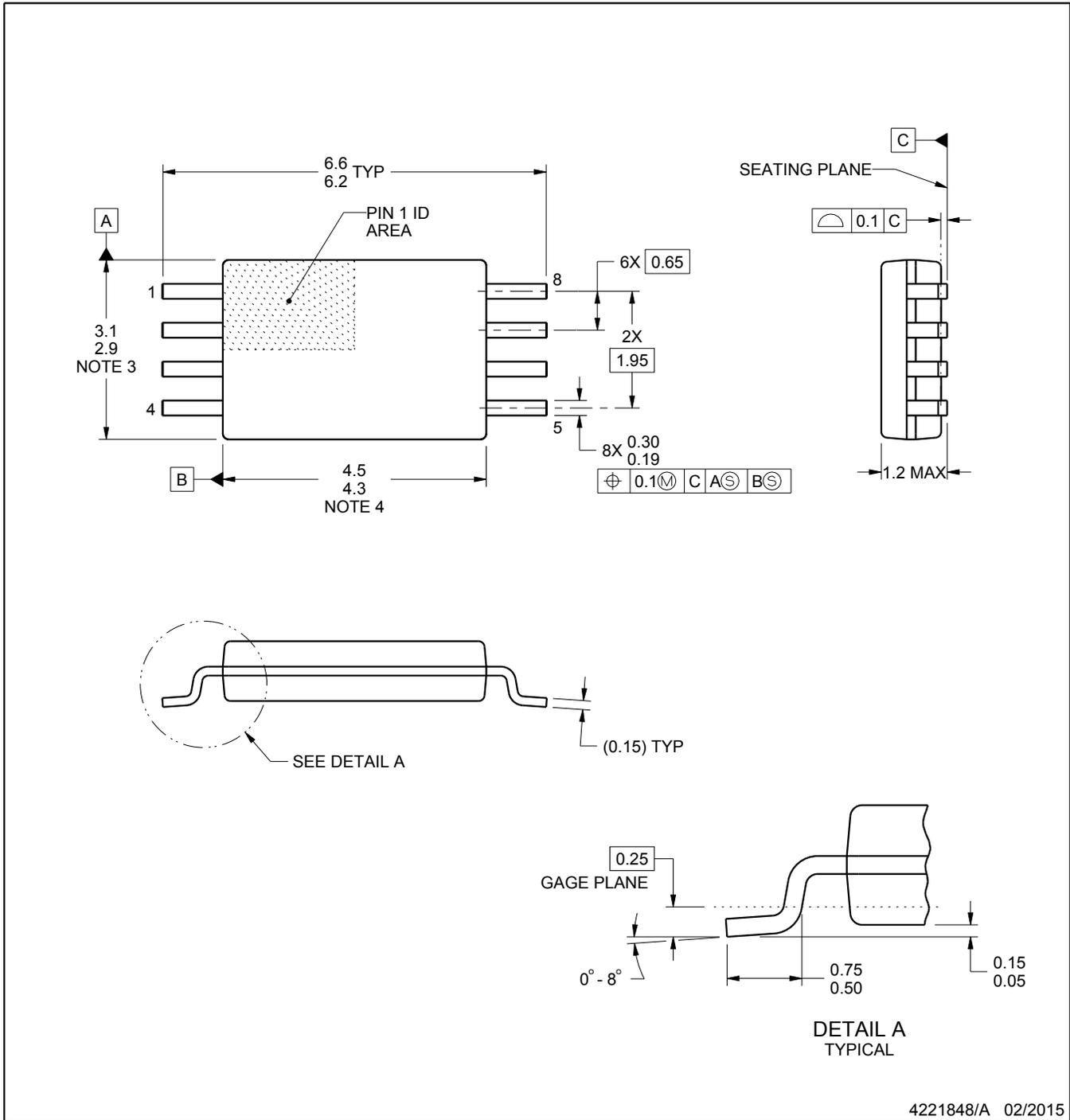
PW0008A



# PACKAGE OUTLINE

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



4221848/A 02/2015

### NOTES:

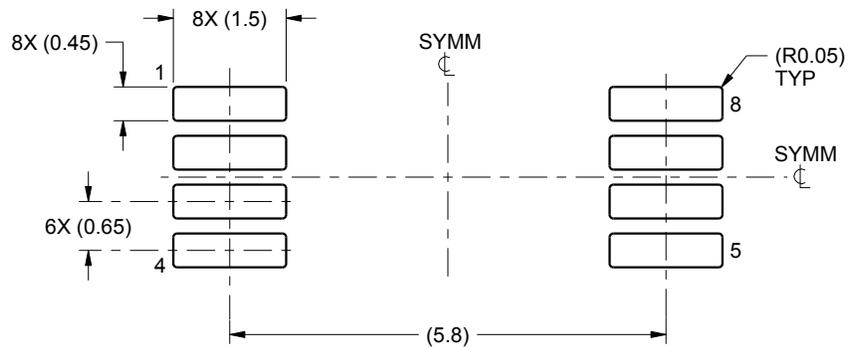
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153, variation AA.

# EXAMPLE BOARD LAYOUT

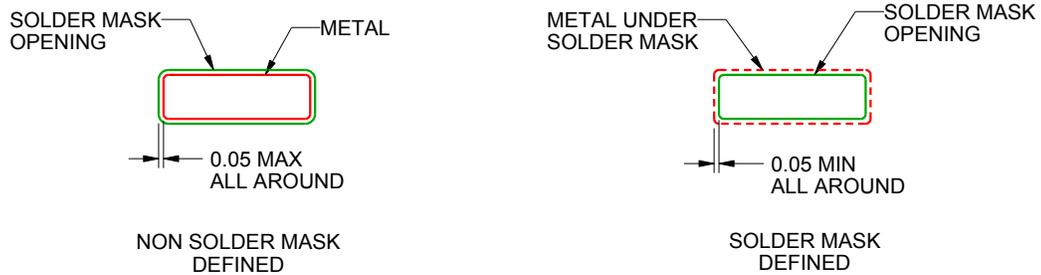
PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
SCALE:10X



SOLDER MASK DETAILS  
NOT TO SCALE

4221848/A 02/2015

NOTES: (continued)

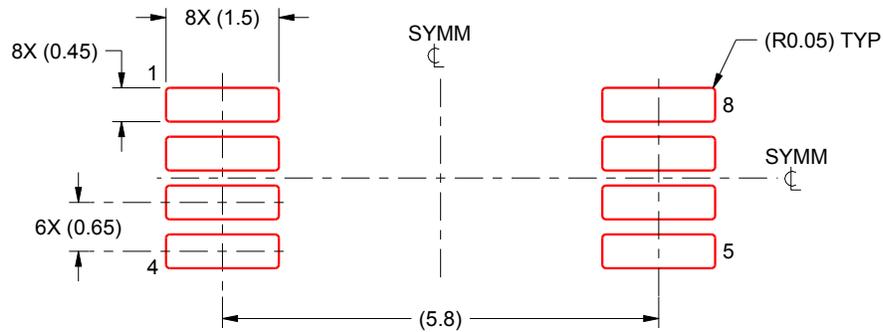
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:10X

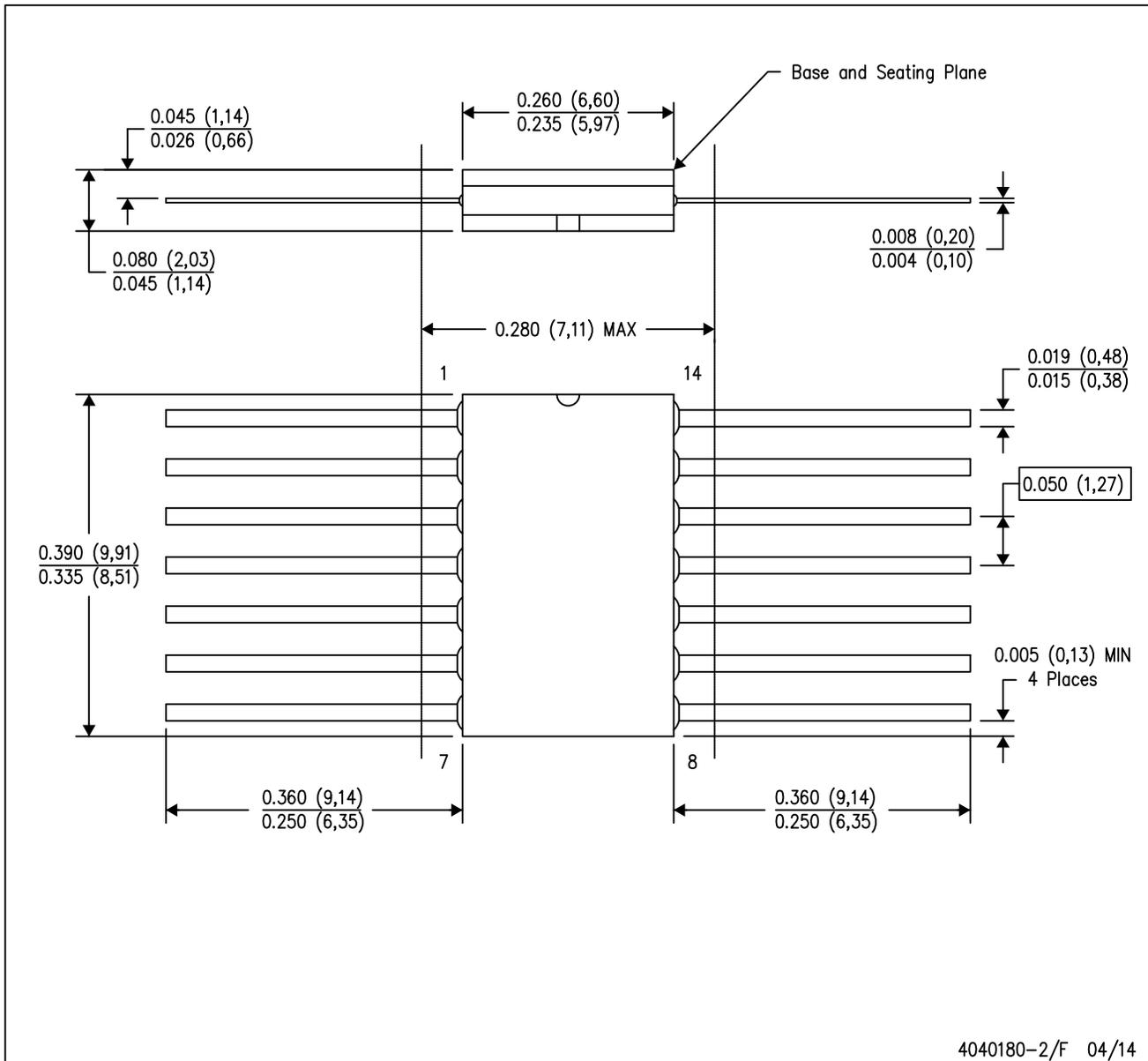
4221848/A 02/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. This package can be hermetically sealed with a ceramic lid using glass frit.
  - D. Index point is provided on cap for terminal identification only.
  - E. Falls within MIL STD 1835 GDFP1-F14

## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#), [TI's General Quality Guidelines](#), or other applicable terms available either on [ti.com](http://ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2026, Texas Instruments Incorporated

Last updated 10/2025